

SPECTROSCOPIC ROTATING COMPENSATOR ELLIPSOMETER SYSTEM WITH
PSEUDO-ACHROMATIC RETARDER SYSTEM

This Application is a Continuation-In-Part of:

5 Co-pending Application Serial No. 09/945,962 filed 09/04/01; and
Co-pending Application Serial No. 09/496,011 filed 02/01/00;
which is a CIP from Application Serial No. 09/246,888 filed
02/08/99, (now Patent No. (6,084,675);
10 which is a CIP from Application Serial No. 08/912,211 filed Aug.
15, 1997, (now Patent No. 5,872,630);
which is a CIP from Application Serial No. 08/530,892 filed
09/20/95, (now Patent No. 5,666,201);
and is a CIP of Application Serial No. 08/618,820 filed
15 03/20/96, (now Patent No. 5,706,212);
This Application is, via the Co-Pending Application 09/496,011
and Application 09/246,888 further a Continuation-In-Part of
Applications Serial Nos. 09/225,118 (now Patent 6,084,674);
09/223,822 (now Patent 6,118,537); 09/232,257 (now Patent
20 6,141,102); 09/225,371 (now Patent 6,100,981); 09/225,076 (now
Patent 5,963,325); which Applications depend from Application
Serial No. 08/997,311 filed 12/23/97, now Patent 5,946,098.

25 TECHNICAL FIELD

30 This invention relates to ellipsometers and polarimeters and
the like, and more particularly is a Spectroscopic Rotating
Compensator Ellipsometer System including a Pseudo-Achromatic
Compensator providing, over a range of wavelengths, a range of
retardations, (ie. maximum retardance minus minimum retardance),
of less than 90 degrees, said range of retardations being
bounded by a minimum of preferably at least 30 degrees, to a
maximum of less than 135 degrees. Said System also comprises a
detector means for simultaneously detecting a Multiplicity of

Wavelengths, which Spectroscopic Rotating Compensator Ellipsometer System is calibrated by a Mathematical Regression based technique involving, where beneficial and desired, Parameterization of Calibration Parameters. Preferred embodiments provide a preferred fast axes offset, dual or triple zero-order, or dual or triple effective zero-order, or combination zero-order and effective zero-order waveplate compensator means system; alternative use of D.C. or A.C, and combination A.C. and D.C. data normalizing bases in various calibration steps and use of un-normalized signals to determine reflectance, as well as use of various samples during calibration data acquisition. Said invention system can be realized utilizing off-the-shelf, non-ideal, waveplates combined to provide a compensator which presents a fast axis azimuth which varies with wavelength.

BACKGROUND

Ellipsometry is a well known means by which to monitor material systems, (samples). In brief, a polarized beam of electromagnetic radiation of one or more wavelengths is caused to impinge upon a material system, (sample), along one or more angles of incidence and then interact with a material system, (sample). Beams of electromagnetic radiation can be considered as comprised of two orthogonal components, (ie. "P" and "S"), where "P" identifies a plane which contains both an incident beam of electromagnetic radiation, and a normal to an investigated surface of a material system, (sample), being investigated, and where "S" identifies a plane perpendicular to the "P" plane and parallel to said surface of said material system, (sample). A change in polarization state in a polarized beam of electromagnetic radiation caused by said interaction with a material system, (sample), is representative of properties of said material system, (sample). (Note Polarization State basically refers to a magnitude of a ratio of orthogonal

component magnitudes in a polarized beam of electromagnetic radiation, and a phase angle therebetween.) Generally two well known angles, (PSI and DELTA), which characterize a material system, (sample), at a given Angle-of-Incidence, are determined by analysis of data which represents change in polarization state. Additional sample identifying information is often also obtained by application of ellipsometry, including layer thicknesses, (including thicknesses for multilayers), optical thicknesses, sample temperature, refractive indices and extinction coefficients, index grading, sample composition, surface roughness, alloy and/or void fraction, parameter dispersal and spectral dependencies on wavelength, vertical and lateral inhomogenities etc.

Continuing, Ellipsometer Systems generally include a source of a beam of electromagnetic radiation, a Polarizer means, which serves to impose a linear state of polarization on a beam of electromagnetic radiation, a Stage for supporting a material system, (sample), and an Analyzer means which serves to select a polarization state in a beam of electromagnetic radiation after it has interacted with a material system, (sample), and pass it to a Detector System for analysis therein. As well, one or more Compensator(s) can be present and serve to affect a phase angle change between orthogonal components of a polarized beam of electromagnetic radiation.

It is noted that Spectroscopic Ellipsometer Systems utilize a Source which simultaneously provides a plurality of Wavelengths, which Source can be termed a "Broadband" Source of Electromagnetic radiation.

A number of types of ellipsometer systems exist, such as those which include rotating elements and those which include modulation elements. Those including rotating elements include

Rotating Polarizer (RP), Rotating Analyzer (RA) and Rotating Compensator (RC). The presently disclosed invention comprises a Rotating Compensator Ellipsometer System. It is noted that Rotating Compensator Ellipsometer Systems do not demonstrate "Dead-Spots" where obtaining data is difficult. They can read PSI and DELTA of a Material System, (Sample), over a full Range of Degrees with the only limitation being that if PSI becomes essentially zero (0.0), one can't then determine DELTA as there is not sufficient PSI Polar Vector Length to form the angle between the PSI Vector and an "X" axis. In comparison, Rotating Analyzer and Rotating Polarizer Ellipsometers have "Dead Spots" at DELTA's near 0.0 or 180 Degrees and Modulation Element Ellipsometers also have "Dead Spots" at PSI near 45 Degrees. The utility of Rotating Compensator Ellipsometer Systems should then be apparent. Another benefit provided by fixed Polarizer (P) and Analyzer (A) positions is that polarization state sensitivity to input and output optics during data acquisition is essentially non-existent. This enables relatively easy use of optic fibers, mirrors, lenses etc. for input/output.

A Search for relevant Patents has identified very little. Most important is a Patent to Johs et al., Serial No. 5,872,630, from which the present Application is derived as a CIP. Said 630 Patent describes:

A spectroscopic rotating compensator material system investigation system comprising a source of a polychromatic beam of electromagnetic radiation, a polarizer, a stage for supporting a material system, an analyzer, a dispersive optics and at least one detector system which contains a multiplicity of detector elements, said spectroscopic rotating compensator material system investigation system further comprising at least one

compensator(s) positioned at a location selected from the group consisting of:

before said stage for supporting a material system;

after said stage for supporting a material system; and

both before and after said stage for supporting a material system;

such that when said spectroscopic rotating compensator material system investigation system is used to investigate a material system present on said stage for supporting a material system, said analyzer and polarizer are maintained essentially fixed in position and at least one of said at least one compensator(s) is caused to continuously rotate while a polychromatic beam of electromagnetic radiation produced by said source of a polychromatic beam of electromagnetic radiation is caused to pass through said polarizer and said compensator(s), said polychromatic beam of electromagnetic radiation being also caused to interact with said material system, pass through said analyzer and interact with said dispersive optics such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements in said at least one detector system.

Said 630 Patent also, amongst other disclosure, describes a Mathematical Regression based Calibration procedure which makes

possible the use of essentially any compensator regardless of non-achromatic characteristics.

Another Patent to Johs, from which the 630 Patent was Continued-in Part, is No. 5,666,201, filed 09/20/95. The focus in said 201 Patent comprises a detector arrangement in which multiple orders of a dispersed beam of electromagnetic radiation are intercepted by multiple detector systems. However, Claim 8 in the 201 Patent, in combination with a viewing the Drawings therein, provide conception of the Spectroscopic Rotating Compensator Ellipsometer, as Claimed in Claim 1 of the JAW 630 Patent and, in fact, the the 630 Patent issued in view of a Terminal Disclaimer based upon the 201 Patent.

Also disclosed is Patent No. 5,706,212, Issued 01/06/98, and Filed 03/20/96 for an Infrared Ellipsometer System Regression based Calibration Procedure. Said 212 Patent describes use of an Substantially Achromatic Rotating Compensator and application of Mathematical Regression in a Calibration procedure which evaluates calibration parameters in both rotating and stationary components. The 212 Patent describes that 2 OMEGA and 4 OMEGA associated terms are generated by a detector of a signal which passes through a compensator caused to rotate at a rate of OMEGA. Said 630 Patent was Continued-in-Part therefrom, as is the present Application via an intervening Patent Application. It is noted that the 212 Patent Application was filed four months prior to the earliest priority Patent Application, of Aspnes et al. Patents, (ie. Nos. 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859), the later of which was Filed on 7/24/96.

Relevant Patents to Aspnes et al. are Nos. 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859. These Patents describe a Broadband Spectroscopic Rotating Compensator Ellipsometer System

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wherein the Utility is found in the use of a "substantially Non-Achromatic" compensator, (see Claim 1 in the 657 Patent), and selecting a Wavelength Range and Compensator so that "an effective phase retardation value is induced covering at least from 90 degrees to 180 degrees", (012 Patent), over a range of wavelengths of at least 200 - 800 nm. The 787 and 859 recite that at least one wavelength in said wavelength Range has a retardation imposed of between 135 and 225 Degrees, and another wavelength in the wavelength Range has a retardation imposed which is outside that retardation Range. The Utility of the Therma-wave Patents derives from the identified conditions being met so that at least one of a 2 OMEGA and a 4 OMEGA coefficient provided by a detector provides usable information at a wavelength, even when said coefficient does not provide usable information at other wavelengths. Again, the identified Aspnes et al. Patents recite directly, or describe the presence of a "substantially-non-Achromatic" compensator, while, it is noted at this point, the invention disclosed in this Application utilizes what are properly termed substantially-achromatic or Psuedo-Achromatic compensators. It is further noted that the 5,716,212 Patent Application, from which this Application Continues-in-Part, was filed prior to 07/24/76 filing date of the 859 Aspnes et al. priority Patent Application. The disclosed invention then has Priority to simultaneous use of 2 OMEGA and 4 OMEGA signals provided from a detector in a spectroscopic rotating compensator ellipsometer system which utilizes "Other-Than-Substantially Non-Achromatic" Compensators, namely "Substantially-Achromatic" or "Pseudo-Achromatic" Compensators, to characterize samples, emphasis added.

A recently published PCT Application is No. WO 01/90687 A2, which is based on US Application Serial No. 09/575,295 filed 05/03/01. This Application was filed by Thermawave Inc. and specifically describes separate use of a 2ω and a 4ω term to provide insight to sample thickness and temperature.

Another Patent, No. 4,053,232 to Dill et al. describes a Rotating-Compensator Ellipsometer System, which operates utilizes monochromatic light.

Two Patents which identify systems which utilize Polychromatic light in investigation of material systems, Nos. 5,596,406 and 4,668,086 to Rosencwaig et al. and Redner, respectively, were also identified.

Also identified is a Patent to Woollam et al, No. 5,373,359 as it describes a Rotating Analyzer Ellipsometer System which utilizes white light. Patents continued from the 359 Woollam et al. Patent are, Nos. 5,504,582 to Johs et al. and 5,521,706 to Green et al. Said 582 Johs et al. and 706 Green et al. Patents describe use of polychromatic light in a Rotating Analyzer Ellipsometer System.

A Patent to Bernoux et al., No. 5,329,357 is identified as it describes the use of optical fibers as input and output means in an ellipsometer system.

A Patent to Chen et al., No. 5,581,350 is identified as it describes the application of regression in calibration of ellipsometer systems.

Additionally, Patents pertaining to optical elements, and particularly to compensators/retarders per se are:

Patent No. 4,917,461 to Goldstein, describes an achromatic infrared retarder comprised of two identical prisms in combination with a reflective surface;

Patent No. 4,772,104 to Buhner which describes an achromatic optical filter comprised of two birefringent disks;

Patent No. 4,961,634 to Chipman describes an infrared

achromatic retarder comprised of CdS and CdSe plates aligned with the fast axes thereof perpendicular to one another;

Patent No. 5,946,098 to Johs, Herzinger and Green, which describes numerous optical elements. In addition Patents to Johs et al. Nos. 6,084,674; 6,118,537; 6,100,981; 6,141,102; 6,100,981; 5,963,325; 6,084,674 and to Herzinger et al. 6,084,675, which Applications depend from Application Serial No. 08/997,311 filed 12/23/97, now said Patent 5,946,098;

Additional Patents which describe Compensators are Patent No. 548,495 to Abbe; Patent No. 4,556,292 to Mathyssek et al.; Patent No. 5,475,525 Tournois et al.; Patent No. 5,016,980 Waldron; and Patent No. 3,817,624 to Martin and Patent No. 2,447,828 to West;

And, Patents to Robert et al., No. 4,176,951 and 4,179,217 are also disclosed as they describe rotating Birefringent elements in Ellipsometers which produce 2ω and 4ω components.

Regarding Articles, an article by Johs, titled "Regression Calibration Method For Rotating Element Ellipsometers", which appeared in Thin Film Solids, Vol. 234 in 1993 is also identified as it predates the Chen et al. Patent and describes an essentially similar approach to ellipsometer calibration.

An article by Jellison Jr. titled "Data Analysis for Spectroscopic Ellipsometry", Thin Film Solids, 234, (1993) is identified as it describes a method for determining the accuracy with which certain data points can be measured, which information allows adding a weighting factor to a curve fitting regression procedure as applied to a multiplicity of data points, said weighting factor serving to emphasize the effect of more accurate and precise data.

5 An article by Collins titled "Automated Rotating Element Ellipsometers: Calibration, Operation, and Real-Time Applications", Rev. Sci. Instrum. 61(8), August 1990 is identified as it provides insight into rotating element ellipsometers.

10 An article by Kleim et al. titled "Systematic Errors in Rotating-Compensator Ellipsometry" published in J. Opt. Soc. Am./Vol. 11, No. 9, Sept 1994 is identified as it describes calibration of rotating compensator ellipsometers.

15 An Article by An and Collins titled "Waveform Analysis With Optical Multichannel Detectors: Applications for Rapid-Scan Spectroscopic Ellipsometer", Rev. Sci. Instrum., 62 (8), August 1991 is also identified as it discusses effects such as Detection System Error Characterization, Stray Light, Image Persistence etc., and calibration thereof.

20 Further identified as authority for Matrix Mathematics is a paper by Jones titled "A New Calculus For The Treatment Of Optical Systems", J.O.S.O., Vol. 31, (July 1941).

25 Identified as describing application of Mueller Matricies in Rotating Compensator Ellispometers which utilize imperfect compensators, is a paper by Hauge titled "Mueller Matrix Ellipsometry With Imperfect Compensators", J. Opt. Soc. Am., Vol. 68, No. 11, (Nov. 1978).

30 A paper titled "Analysis of Specular and Textured SnO_2 :F Films by High Speed Four-Parameter Stokes Vector Spectroscopy", Rovira & Collins, J. App. Phys., Vol. 85, No. 4, (1999).

Papers by Schubert and Schubert et al. which describe

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5 "Generalized Ellipsometry" are disclosed as they provide insight
as how to Mathematically treat depolarizing Elements. Said
Articles are: "Polarization Dependent Parametes of Arbitrary
Anisotropic Homogeneous Epitaxial Systems", Phys. Rev. B 53,
(1996); "Generalized Transmission Ellipsometry For Twisted
Biaxial Dielectric Media: Application to Chiral Liquid
Crystals", J. Opt. Soc. Am A, Vol 13, No. 9 (1996); and
"Extrenson of Rotating-Analyzer Ellipsometry to Generalized
Ellipsometry: Determination of the Dielectric Function Tensor
10 From Uniaxial TiO2", J. Opt. Soc. Am. A. 13, (1996).

15 A book by Azzam and Bashara titled "Ellipsometry and
Polarized light" North-Holland, 1977 is disclosed and
incorporated herein by reference for general theory.

As well, identified for authority regarding regression, is
a book titled Numerical Recipes in "C", 1988, Cambridge
University Press.

20 Even in view of the foregoing, a need remains for improved
Spectroscopic Rotating Compensator Ellipsometer Systems,
including a Photo Array, for simultaneously detecting a
Multiplicity of Wavelengths, and which can be realized utilizing
25 off-the-shelf, non-ideal, compensators and diode array
spectrometers. As will be better disclosed in the Disclosure of
the Invention Section of this Specification, the invention
provides a Spectroscopic Rotating Compensator Ellipsometer
System which comprises a .Psuedo-Achromatic Compensator, and
discloses alternative use of D.C. and A.C data normalization in
30 various calibration steps, as well as use of un-normalized
signals in determining Reflectance.

DISCLOSURE OF THE INVENTION

First, it should be appreciated that the purpose of this Application is to achieve a Patent which clarifies the boundaries of what the Patents to Aspnes et al., Nos. 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859, (all assigned to Thermawave Inc.), cover as contrasted to what Patents Nos. 5,706,212 and 5,872,630, and a Patent to Issue based on Application Serial No. 09/496,011 filed 02/01/00; (all assigned to J.A. Woollam Co. Inc.), cover. It is directly stated that it is believed that Thermawave has rights for application of "Substantially- Non-Achromatic" Compensators in Spectroscopic Rotating Compensator Ellipsometers, while the J.A. Woollam Co. Inc. has rights for application of "Substantially-Achromatic/Psuedo-Achromatic" Compensators in Spectroscopic Rotating Compensator Ellipsometers. This is partially based in that the priority of the Thermawave 859 Patent, (which discloses a Substantially-Non-Achromatic Retarder which provides a retardation range that passes through 180 degrees), is approximately 4 months later than the priority of the J.A. Woollam Co. 212 Patent, (which discloses a Substantially-Achromatic/Psuedo-Achromatic Retarder). The distinction between Achromatic and Substantially-Achromatic/Psuedo-Achromatic is that an Achromatic Retarder ideally provides the same retardation in all wavelengths over a range of wavelengths, while a Substantially Achromatic/Psuedo-Achromatic Retarder provides retardance over a range of wavelengths, which varies. The distinction between "Substantially-Non-Achromatic" and "Substantially-Achromatic/Psuedo-Achromatic" Retarders is that the former provide a retardation range which is, over a range of wavelengths, more than that provided by the later. It is believed that a good delineation line between Substantially-Non-Achromatic and Substantially-Achromatic/Psuedo-Achromatic Retarders is provided by the recitation in the Thermawave 012 Patent wherein it is

stated that "an effective phase retardation value is induced covering at least from 90 degrees to 180 degrees", over a range of wavelengths. In the present Specification the terminology Substantially-Achromatic/Pseudo-Achromatic is used to identify a Compensator that provides a range of retardations, over a range of wavelengths, which range of retardations, (ie. maximum retardation minus minimum retardation), is less than 90 degrees. And the distinction between Substantially-Achromatic and Pseudo-Achromatic, for the purposes of this Specification is considered to be that the former provides a range of retardation values, over a range of wavelengths, greater than 0.0 degrees and merging into the range of a Pseudo-Achromatic Compensator which, for the purposes of this Specification can be considered as providing a magnitude of retardations less than the magnitude of "at least from 90 to 180 degrees", (eg. the retardation provided by a J.A. Woollam Co. Pseudo-Achromatic Compensator varies with wavelength over a range, (that is, maximum - minimum retardation), of less than 90 degrees, with a preferred lower boundary value retardation being at least 30 degrees, and an upper boundary value of retardation being less than 135 degrees). It is believed that the Thermawave Patents do not provide priority support for Claiming, in the context of a Rotating Compensator Spectroscopic Ellipsometer, a retarder with other than Substantially-Non-Achromatic characteristics, while the J.A. Woollam Co. has priority support for Claiming Substantially-Achromatic/Pseudo-Achromatic Compensators applied in the context of a Rotating Compensator Spectroscopic Ellipsometer from the 212 and 630 Patents, with refined definition for Pseudo-Achromatic being provided by, for instance, the Allowed but still Co-pending Application Serial No. 09/496,011, which was filed 02/01/00.

Moving along, as described in the 630 Patent, prior

thereto it was generally considered that while Rotating Compensator Ellipsometers Systems provide many benefits, (eg. Material System, (Sample), PSI and DELTA investigation limiting "dead-spots" are not present), that in the absence of essentially Achromatic "ideal" Compensators it would be prohibitively difficult and expensive to build, calibrate and utilize a "Spectroscopic" Rotating Compensator Ellipsometer Material System Investigating System. This is to be understood in light of the fact that Compensator Means which are essentially Achromatic, (ie. provide essentially constant retardation, (ie. very small retardation range), over a large range of Wavelengths, such as from, less than or equal to 190, to 1000 or higher (eg. 1800 nm), nanometers), are not generally and economically available as off-the-shelf items, (this being particularly true where a Compensator is rotated during use).

In the terminology of the 630 Patent, the disclosed invention system is, however, an affordable, easy to calibrate and utilize Spectroscopic Rotating Compensator Material System Investigation System comprising a Source of a Polychromatic Beam of Electromagnetic Radiation, a Polarizer, a Stage for Supporting a Material System, (Sample), an Analyzer, a Dispersive Optics and at least one Photo Array Detector Element System which contains a multiplicity of Detector Elements, which Spectroscopic Rotating Compensator Material System Investigation System further comprises at least one Compensator(s) positioned at a location selected from the group consisting of: (before said stage for supporting a Material System, (Sample), and after said stage for supporting a Material System, (Sample), and both before and after said stage for supporting a Material System (Sample)).

While the preferred embodiment of the disclosed invention utilizes Psuedo-Achromatic Compensators, technically of interest

is the fact that said at least one Compensator(s) utilized in the disclosed invention can technically be essentially any available, reasonably priced, off-the-shelf Retardation providing system, including non-Achromatic Berek-type, Zero-Order Waveplate, Multiple-Order Waveplate, Zero-Order Waveplate constructed from Multiple Multiple-Order Waveplates, Sequential Systems of Multiple Zero-Order Waveplates, each of which can be constructed from Multiple Multiple-Order Waveplates, Polymer Retarder, Mica Waveplate, Freshnel Rhomb, Achromatic, and Pseudo-Achromatic, etc. For general information, it is noted that a Berek-type Compensator is a uniaxially anisotropic plate of material in which the Optical Axis is oriented perpendicularly to a plate surface thereof. When a Polarized Beam of Electromagnetic Radiation is caused to be incident other than along the Optical Axis, orthogonal components thereof encounter different effective Indices of Refraction, thereby effecting retardation therebetween. Polymer Compensators are made of a polymer material and can provide true Zero-Order retardance which, as do many Compensators, provides an inverse wavelength functional Retardance Characteristic. Essentially Achromatic (Pseudo-Achromatic) Compensators can be constructed by stacking appropriately chosen Polymer and Crystal waveplates.

Sequential Systems of Multiple Zero-Order Waveplates allow achieving flattened Retardance vs. Wavelength characteristics, (ie. smaller retardation range), and it is noted, are the preferred disclosed invention Compensator type. To elaborate, the preferred Compensator system comprises a system of at least two (eg. First and Second), Zero-Order Waveplates, each of which Zero-Order Waveplates can be a single plate, (eg. mica or polymer), or constructed from an effective combination of

Multiple-Order Waveplates, (eg. two quartz plates or
bicrystalline waveplates such as Cadmium Sulfide or Cadmium
Selenide). As further insight, an effective Zero-Order
Waveplate can be functionally constructed by combining two
5 Multi-Order (eg. Quartz) Waveplates which have Optical Axes
oriented at a nominal ninety (90) degrees with respect to one
another. That is, two Multi-Order waveplates are selected and
combined so that the difference in retardation entered by each
gives rise to an overall Zero-Order Waveplate retardance
10 characteristic. In particular, the preferred invention
Compensator embodiment provides that each of said First and
Second effectively Zero Order Waveplates be formed by physically
optically combining two Multiple Order Waveplates, such that
the net result of passing a beam of electromagnetic radiation
15 therethrough is essentially equivalent to the result which would
achieved by passing said electromagnetic beam through a single
plate Zero-Order Waveplate. The reason that such effective
Zero-Order Waveplates, which are formed by physically combining
two Multiple Order Waveplates are preferred, is that such
20 effectively Zero-Order Waveplates are readily and economically
available in the marketplace, and that true single plate
Zero-Order Waveplates are typically physically delicate and
difficult to utilize. Continuing, the preferred invention
Compensator provides that two of said per se., or effective
25 Zero-Order Waveplate Compensators, be oriented with respect to
one another such that the fast axes of the First per se. or
effectively Zero-Order Compensator are rotated with respect to
the Second per se. or effectively Zero-Order Compensator, away
from zero or ninety degrees, and typically within some range
30 around a nominal forty-five (45) degrees. In use, a beam of
electromagnetic radiation utilized to investigate a material
system, is caused to pass through both of said First and Second
Compensators with the result achieved being that a disclosed
invention preferred Compensator configuration provides a

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p pseudo-achromatic retardation range, (ie. max - min), of less
than 90 degrees within a range of retardations bounded by a
lower bound of at least thirty (30) and an upper bound of less
one-hundred-thirty-five (135) degrees, over relatively large
5 wavelength ranges within, for instance, one-hundred-ninety (190
NM) to eighteen-hundred (1800 NM). That is, preferred
invention Compensators are specifically designed to provide
retardation values which never equal or exceed one-hundred-
eighty (180) degrees, or even one-hundred-thirty-five (135)
10 degrees at any utilized wavelength. It is noted that this is
in direct contrast to the practice of Therma-wave rotating
compensator systems as described in Patent No. 6,320,657 B1,
6,134,012, 5,973,787 and 5,877,859 to Aspnes, wherein large
chromaticities, (eg. at least 90 - 180 degrees retardation range
15 over a range of wavelengths), in compensator systems utilized
cover a range of retardations which the Specifications indicate
can include 180 degrees therewithin, emphasis added.

20 In terminology similar to that used in the Aspnes et al.
Patents, which describe spectroscopic ellipsometer systems
comprising substantially non-achromatic compensators, the
presently disclosed invention can be described as:

25 A spectroscopic ellipsometer for evaluating a sample
comprising:

a broadband light source generating a beam having wavelengths
extending over a range of at least 200 to 800 nm;

30 a polarizer disposed in the path of the light beam;

a compensator disposed in the path of the light beam, said
compensator for inducing phase retardations in the polarization
state of the light beam, said compensator having

characteristics selected from the group consisting of:

being substantially achromatic;

being pseudo-achromatic; and

being other than substantially non-achromatic;

so that the amount of phase retardation varies with wavelength, over a range of wavelengths, less than is the case were a substantially-non-achromatic compensator utilized, said compensator means being rotated at an angular frequency of ω ;

an analyzer that interacts with the light beam after the beam interacts with the sample and with the compensator;

a detector means that measure the intensity of the light beam after the interaction with the analyzer at a plurality of wavelengths across the wavelength range of at least 200 to 800 nm;

said detector means generating a time varying intensity output signal simultaneously comprising 2ω and 4ω component signals; and

optionally a processor for evaluating the sample based on simultaneous use of the intensity output signal 2ω and 4ω components.

(It is to be noted that the present Application is a CIP from Application Serial No. 08/618,820 filed 03/20/96, (now Patent No. 5,706,212), which disclosed a spectroscopic ellipsometer sytem which was disclosed as preferably comprising a substantially achromatic compensator).

Another recitation of the presently disclosed invention, which

focuses on the presence of a Psuedo-Achromatic Compensator, is:

A spectroscopic ellipsometer for evaluating a sample comprising:

polychromatic electromagnetic radiation source means generating a beam having wavelengths extending over a range of at least 200 to 800 nm;

polarizer means disposed in the path of said beam;

compensator(s) means disposed in the path of the beam, said compensator for inducing phase retardations in the polarization state of the light beam, said compensator(s) means being:

pseudo-achromatic;

in that the amount of phase retardation varies more with wavelength than is the case if a substantially achromatic compensator is utilized but in that the amount of phase retardation varies less than is the case if a substantially non-achromatic compensator is utilized, said compensator means being rotated at an angular frequency of ω ;

analyzer means that interacts with the beam after the beam interacts with the sample and the compensator means;

detector means that measure the intensity of the beam after the interaction with the analyzer at a plurality of wavelengths across the wavelength range of at least 200 to 800 nm;

said detector means generating a time varying intensity output signal simultaneously comprising 2ω and 4ω component signals, said 2ω and 4ω signals being simultaneously

present at all wavelengths measured unless the 2ω signal is forced to 0.0 by a sample presenting with an ellipsometric DELTA of 0.0, as opposed to being caused to be 0.0 by said compensator means; and

5 optionally a processor for evaluating the sample based on simultaneous use of the intensity output signal 2ω and 4ω components.

10 Further, for the purposes of this Specification, the definition of "other than substantially non-achromatic" includes the requirement that the range of retardations entered to wavelengths over a range of wavelengths does not include one-hundred-eighths (180) degrees.

15 (Note in both the foregoing recitations, in contrast to the teachings of the Aspnes et al. Patents Nos. 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859, the compensator means in a disclosed invention system can not force the 2ω signal to (0.0), as it is selected to provide, at any wavelength, far less than 180 degrees retardation, (eg, greater than 30 up to 120 degrees; or 35 to less than 125; or 45 degrees to less than 135 degrees etc.), regardless of which wavelength in the polychromatic range of wavelengths of at least 200 to 800 nm, 20 (eg. 190 - 1800 nm), is investigated. Note, in any case the range of retardation values entered to wavelengths over a range thereof is less than ninety (90) degrees and does not include 180 degrees. Further, it is to be understood the terminology "Compensator" means include the case of a disclosed invention 25 system being comprised of a Single Compensator or Multiple Compensator Elements).

30 Continuing, the disclosed invention system preferably utilizes at least one compensator means which is described as a

selection from the group consisting of:

being comprised of at least two zero-order waveplates, said zero-order waveplates having their respective fast axes rotated to a position offset from zero or ninety degrees with respect to one another;

being comprised of a combination of at least a first and a second effective zero-order wave plate, said first effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes of the multiple order waveplates in said second effective zero-order wave plate being rotated to a position at a nominal forty-five degrees to the fast axes of the multiple order waveplates in said first effective zero-order waveplate;

being comprised of a combination of at least a first and a second effective zero-order wave plate, said first effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes of the multiple order waveplates in said second effective zero-order wave plate being rotated to a position away from zero or ninety degrees with respect to the fast axes of the multiple order

waveplates and in said first effective zero-order waveplate;

being comprised of at least one zero-order waveplate and one effective zero-order waveplate, said effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, the fast axes of the multiple order waveplates in said effective zero-order wave plate being rotated to a position away from zero or ninety degrees with respect to the fast axis of the zero-order waveplate.

(Note, zero-order and effective zero-order waveplates are of, for instance, single plate and multiple waveplate construction respectively).

(It is also noted that generally the more elements combined to form a compensator, the smaller can be made the range over which retardation values vary with wavelength, over a range of wavelengths. For instance three (3) elements are utilized in some J.A. Woollam CO. Psuedo-Achromatic Compensators which operate over a major part of the range of 190 - 1700 nm).

Continuing, because the preferred disclosed invention Compensators do not provide an exact Ninety (90) Degrees of Retardation at all wavelengths over a relatively large range of Wavelengths, the presently disclosed invention, as described herein, utilizes a Regression based Calibration procedure which compensates for said non-ideal Compensator Retardation characteristics. And while it is true that the sensitivity and accuracy of a Rotating Compensator Material System Investigation System degrades as the Retardance provided by a utilized Compensator approaches zero (0.0) or one-hundred-eighty (180) degrees, again, it has been found that Compensators which

100-4300-1-3001
5 demonstrate a Retardation range of less than Ninety (90) degrees (max - min) over a range of utilized Wavelengths, within in a range bounded by at least Thirty (30) and less than one-hundred-thirty-five (135) degrees, (thereby avoiding the 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859 Patents to Aspnes et al.), are available, or can be constructed from readily available components, which are very acceptable for use in the disclosed invention Rotating Compensator Ellipsometer System, and said Compensators enable achieving very impressive results over a demonstrated relatively large range of wavelengths, (eg. at least two-hundred-fifty (250) to one-thousand (1000) or more nanometers). One embodiment of the spectroscopic rotating compensator material system investigation system typically comprises at least one compensator(s) which produces a retardance of, preferably, between seventy-five (75) and one-hundred-thirty (130) degrees over a range of wavelengths defined by a selection from the group consisting of:

- a. between one-hundred-ninety (190) and seven-hundred-fifty (750) nanometers;
- b. between two-hundred-forty-five (245) and nine-hundred (900) nanometers;
- c. between three-hundred-eighty (380) and seventeen-hundred (1700) nanometers;
- d. within a range of wavelengths defined by a maximum wavelength (MAXW) and a minimum wavelength (MINW) wherein the ratio of (MAXW)/(MINW) is at least one-and-eight-tenths (1.8).

Acceptable practice however, provides for the case wherein at

least one of said at least one compensator(s) provides range of Retardation of less than Ninety (90) degrees (max - min) over a range of utilized Wavelengths between MINW and MAXW, within in a range bounded by at least Thirty (30) and less than one-hundred-thirty-five (135) degrees, said wavelength range being specified by a selection from the group consisting of:

- a. MINW less than/equal to one-hundred-ninety (190) and MAXW greater than/equal to seventeen-hundred (1700) nanometers;
- b. MINW less than/equal to two-hundred-twenty (220) and MAXW greater than/equal to one-thousand (1000) nanometers;
- c. within a range of wavelengths defined by a maximum wavelength (MAXW) and a minimum wavelength (MINW) range where $(MAXW)/(MINW)$ is at least four-and-one-half (4.5).

(NOTE, the specified values and ranges can not be achieved by single plates with Substantially Non-Achromatic, (eg. $1/\text{wavelength}$), retardation characteristics, but can be achieved by two (2) and three (3) plate Compensator designs).

Continuing, when the disclosed invention Spectroscopic Rotating Compensator Material System Investigation System, (ie. Spectroscopic Ellipsometer), is used to investigate a Material System, (ie. Sample), present on said Stage for Supporting a Material System, (Sample), said Analyzer Means and Polarizer Means are maintained essentially fixed in position and at least one of said at least one Compensator(s) Means is/are caused to continuously rotate while a Polychromatic, (Broadband), Beam of Electromagnetic Radiation produced by said Source of a

Polychromatic Beam of Electromagnetic Radiation is caused to pass through said Polarizer and said Compensator Means. Said Polychromatic Beam of Electromagnetic Radiation is also caused to interact with said Material System, (Sample), pass through
5 said Analyzer Means and interact with said Dispersive Optics such that a Multiplicity of Essentially Single Wavelengths are caused to simultaneously enter a corresponding multiplicity of Detector Elements in said Detector System Photo Array.

10 In language again similar to that in the Aspnes et al. Patents, a method of calibrating a Spectroscopic Ellipsometer System can comprise the steps of:

15 a. providing a spectroscopic ellipsometer for evaluating a sample comprising:

broadband electromagnetic radiation source means generating a beam having wavelengths extending over a range of at least 200 to 800 nm;

20 polarizer means disposed in the path of said beam;

25 compensator means disposed in the path of the beam, said compensator for inducing phase retardations in the polarization state of the light beam, said compensator means having characteristics other than substantially non-achromatic, said compensator means being rotated at an angular frequency of ω ;

30 analyzer means that interact with the beam after the beam interacts with the sample and the compensator means;

detector means that measure the intensity of the beam after the interaction with the analyzer means at a plurality of wavelengths across the wavelength range of at least 200 to 800

nm;

said detector means generating a time varying intensity signal simultaneously comprising 2ω and 4ω component signals, said
5 2ω and 4ω signals being simultaneously present at all wavelengths measured unless the 2ω signal is forced to 0.0 by a sample presenting with an ellipsometric DELTA of 0.0 as opposed to being caused to be 0.0 by said compensator means;

10 b. developing a mathematical model of said spectroscopic ellipsometer system which comprises as calibration parameter(s) at least one selection from the group consisting of:

effective polarizer means azimuthal angle
15 orientation;

present sample PSI (ψ), as a
function of angle of incidence and a
thickness;

20 present sample DELTA (Δ), as a function of angle of incidence and a thickness;

25 retardations of said compensator means as a function of wavelength;

compensator means azimuthal angle orientation;

30 matrix components of said compensator means; and

analyzer means azimuthal angle orientation;

which mathematical model is effectively a transfer function which enables calculation of electromagnetic beam magnitude detected by a detector element, given magnitude provided by said broadband electromagnetic radiation source means
5 generating a beam having wavelengths extending over a range of at least 200 to 800 nm;

c. causing a polychromatic beam of electromagnetic radiation produced by said broadband electromagnetic radiation source
10 means, to pass through said polarizer means, interact with a sample caused to be in the path thereof, pass through said analyzer means, and enter detector elements in said detector means, with said polychromatic beam of electromagnetic radiation also being caused to pass through said compensator means;

d. obtaining data as described by a selection from the group consisting of:

at least one multi-dimensional data set(s); and
20

least two, at least one-dimensional data sets;

said data set(s) being magnitude values vs. parameter(s) selected from the group consisting of:

25 wavelength;

angle-of-incidence of said polychromatic
beam of electromagnetic radiation with
30 respect to a present material system;

effective or actual azimuthal angle
orientation of one element selected
from the group consisting of:

said polarizer; and

said analyzer;

5 obtained over time, while at least one of said at least one compensator is caused to continuously rotate;

said at least at least one, multi-dimensional data set(s) being obtained utilizing a selection from the group consisting of:

10 all of said at least one multi-dimensional data set(s), being obtained utilizing a single sample;

15 at least one of said at least one multi-dimensional data sets being obtained utilizing one sample, with another of said at least one multi-dimensional data sets being obtained utilizing another sample; and

20 at least one of said at least one multi-dimensional data set(s) being obtained with the spectroscopic ellipsometer oriented in a "straight-through" configuration wherein a polychromatic beam of electromagnetic radiation produced by said broadband electromagnetic radiation source means, generating a beam having wavelengths extending over a
25 range of at least 200 to 800 nm, is caused to pass through said polarizer means, pass through said analyzer means and enter detector elements in said at least one detector system, with said polychromatic beam of electromagnetic radiation also being caused to pass through said
30 compensator means but without being caused to interact with any sample other than open ambient atmosphere;

e. normalizing data in each said at least one, multi-dimensional, data set(s) with respect to a selection from

the group consisting of:

a data set D.C. component;

5

a data set A.C. component;

a parameter derived from a combinations
of a data set D.C. component and a
data set A.C. component;

10

f. performing a mathematical regression of said mathematical
model onto said normalized at least one, multi-dimensional, data
set(s), thereby evaluating calibration parameters in said
mathematical model;

15

said regression based calibration procedure serving to evaluate
parameters in said said mathematical model for non-achromatic
characteristics and/or non-idealities and/or positions of at
least one selection from the group consisting of:

20

effective azimuthal angle of said polarizer means;

azimuthal angle of said compensator means,

25

retardation of said compensator means;

matrix components of said
compensator means;

30

depolarization/Mueller Matrix
components; and

azimuthal angle of said analyzer means.

g. optionally repeating steps e. and f. utilizing a different selection in step e. in normalizing data.

Continuing, the 630 Patent Method of Calibrating a Spectroscopic Rotating Compensator Material System Investigation System describes, in the step of calculating values of Coefficients of a Transfer Function from said Data Set, the calculation of values of Coefficients of a Fourier Series, (eg. $\alpha_1, \alpha_4, \beta_2, \beta_4$, in Eqs. 11-14 supra).

Additionally, said 630 Patent Method of Calibrating a Spectroscopic Rotating Compensator Material System Investigation system can further comprise the step of Parameterizing Calibration Parameters by representing variation as a function of Wavelength, (or perhaps Angle-Of-Incidence of said Polychromatic Beam of Electromagnetic Radiation with respect to a Surface of an Investigated Material System, (Sample), or Other Variable), by a Calibration Parameter containing Mathematical Equation, Calibration Parameter(s) in said Calibration Parameter containing Mathematical Equation being evaluated during said Mathematical Regression. (See Eqs. 50 & 51 below). When this is done the Calibration Parameter containing Mathematical Equation provides a functional relationship, and, it is noted, can even be a constant value over a range of, for instance, Wavelengths and/or Polarizer Azimuthal Angle settings). (Note, said parameterized approach to mathematical regression based calibration parameter evaluation is better described supra herein under the Headings GLOBAL REGRESSION MODES 1, 2 and 3).

It is further noted that the at least Two Dimensional Data Set can be obtained with the Spectroscopic Rotating Compensator Material System Investigation System oriented in a "Straight-Through" or "Material-System-(Sample)-Present" configuration. In the first configuration open atmosphere essentially constitutes a material system, and a Polarized

Electromagnetic Beam passes directly through the Polarizer, Compensator(s) and Analyzer into the Detector System. In the second configuration a Material System, (Sample), is present which presents PSI and DELTA values other than those of the open atmosphere so that a Polychromatic Electromagnetic Beam passes through the Polarizer, possibly a Compensator, and then interacts with a Material System, (Sample), before passing through, possibly a Compensator, an Analyzer and into the Detector System. Compensator(s), it should be understood, can be present before and/or after the Material System, (Sample).

With the above general description of the disclosed invention System and Calibration Method in mind, attention is directed to providing a detailed demonstration of the Calibration Procedure of the disclosed invention as applied to a Spectroscopic Rotating Compensator Ellipsometer System sequentially comprised of:

- Polychromatic Light Source
- Fixed Polarizer Means
- Material Sample, (Sample)
- Continuously Rotating Compensator Means
- Fixed Analyzer Means, and
- Detector Element containing Photo Array.

(Note: the Reflection mode side of Fig. 1 of this Disclosure shows this basic configuration where Compensator Means (C) is considered as removed and only Compensator Means(C') remains present).

It is to be appreciated, however, that the basic approach to calibration described directly, is adaptable for use in systems in which the Continuously Rotating Compensator is placed ahead of a Material System, (Sample), and in systems in which

two Compensators are present, one ahead of, and one after a Material System (Sample), wherein one or both are caused to Continuously Rotate in use. For instance, in the case where a Rotating Compensator is placed ahead of the Material System, (Sample), rather than thereafter, simply exchanging references to Polarizer and Analyzer in equations derived for the case where the Rotating Compensator is placed after the Material System, (Sample), provides the applicable equations.

Transfer function equations for the Rotating Compensator system configured as recited above can be obtained from multiplication of Matrix Representations of the various components, in an appropriate order, in conjunction with Trig function containing Rotation Matrices, which serve to align coordinate systems between components. Eq. 1 shows said Matrix representation:

$$E(P, \Psi, \Delta, C, r_1, r_2, r_3, r_4, A) = \begin{pmatrix} 1 & 0 \\ 0 & 0 \end{pmatrix} \begin{pmatrix} \cos(A) & \sin(A) \\ -\sin(A) & \cos(A) \end{pmatrix} \begin{pmatrix} \cos(C) & -\sin(C) \\ \sin(C) & \cos(C) \end{pmatrix} \begin{pmatrix} r_1 & r_3 \\ r_2 & r_4 \end{pmatrix} \begin{pmatrix} \cos(C) & \sin(C) \\ -\sin(C) & \cos(C) \end{pmatrix} \begin{pmatrix} \sin \Psi \cdot e^{i\Delta} & 0 \\ 0 & \cos \Psi \end{pmatrix} \begin{pmatrix} \cos(P) \\ \sin(P) \end{pmatrix} \quad (1)$$

where: Ψ and Δ are the traditional ellipsometric parameters which describe the Material System, (Sample);

P is the azimuthal orientation of the Polarizer;

C is the azimuthal orientation of the Rotating Compensator;

r_1, r_2, r_3 & r_4 are the Jones Matrix elements which describe the Compensator, (Note that a Jones Matrix is utilized, however, a Mueller Matrix or other Matrix could also be utilized);

A is the azimuthal orientation of the Analyzer.

The Light Intensity which is measured by a Detector is provided by multiplying through the Matrices in Eq. 1 to provide a Complex Result, then multiplying said Complex Result by its Complex Conjugate. Eq. 2 indicates this:

$$I(P, \Psi, \Delta, C, r_1, r_2, r_3, r_4, A) = E(P, \Psi, \Delta, C, r_1, r_2, r_3, r_4, A) \cdot E^*(P, \Psi, \Delta, C, r_1, r_2, r_3, r_4, A) \quad (2)$$

The Intensity Equation $I(t)$, (Eq. 8):

$$I(t) = I_0 (DC + \alpha_2 \cos 2C + \beta_2 \sin 2C + \alpha_4 \cos 4C + \beta_4 \sin 4C) \quad (8)$$

which results from said multiplication is very involved, but can be expressed in terms of intermediate results as provided in Eq. 3 - 7, via Eqs. 9.

$$\begin{aligned} p_1 &= \sin \Psi \cdot (\cos \Delta + i \cdot \sin \Delta) \cdot \cos P \\ p_2 &= \cos \Psi \cdot \sin P \end{aligned} \quad (3)$$

$$\begin{aligned} K_1 &= (p_1 \cdot r_3 + p_2 \cdot r_1) \\ K_2 &= (p_1 \cdot r_1 + p_2 \cdot r_3) \\ K_3 &= (-p_1 \cdot r_4 + p_2 \cdot r_2) \\ K_4 &= (p_1 \cdot r_2 + p_2 \cdot r_4) \end{aligned} \quad (4)$$

$$\begin{aligned} U_1 &= (\cos(A) \cdot K_2 + \sin(A) \cdot K_4) \\ U_2 &= (K_3 + K_2) \cdot \sin(A) + (K_1 - K_4) \cdot \cos(A) \\ U_3 &= (\cos(A) \cdot K_3 + \sin(A) \cdot K_1) \end{aligned} \quad (5)$$

$$\begin{aligned} V_1 &= U_1 \cdot \overline{U_1} & V_2 &= U_2 \cdot \overline{U_2} & V_3 &= U_3 \cdot \overline{U_3} \\ V_4 &= 2 \cdot \text{Re}(U_1 \cdot \overline{U_2}) & V_5 &= 2 \cdot \text{Re}(U_1 \cdot \overline{U_3}) & V_6 &= 2 \cdot \text{Re}(U_2 \cdot \overline{U_3}) \end{aligned} \quad (6)$$

$$\begin{aligned}
T1 &= V1 + V3 & T2 &= V2 + V5 & T3 &= V1 - V3 \\
T4 &= V4 + V6 & T5 &= V4 - V6 & &
\end{aligned}
\tag{7}$$

where Eqs. 9 provide that:

$$\begin{aligned}
DC &= \frac{3}{8} \cdot T1 + \frac{1}{8} \cdot T2 \\
\alpha_2 &= \frac{1}{2} \cdot T3 & \beta_2 &= \frac{1}{4} \cdot T4 \\
\alpha_4 &= \frac{1}{8} \cdot (T1 - T2) & \beta_4 &= \frac{1}{8} \cdot T5
\end{aligned}
\tag{9}$$

and $C = \omega \cdot t$, where ' ω ' is the angular frequency of the continuously rotating Compensator and I_0 is an arbitrary constant.

(It is further noted that Eq. 8 is a truncated Fourier Series, and could include additional, higher harmonic terms).

Equations 1 - 9 are appropriate for a Material System, (Sample), which does not depolarize an Electromagnetic Beam used to investigate a Material System, (Sample), such that Jones Matrix formalism is appropriate. If a Material System, (Sample), is investigated which does depolarize an investigation electromagnetic beam, then Mueller Matrix formalism can be substituted. As well, the "Isotropic" Material System, (Sample), Matrix in Eq. 1 could be replaced by a General Material System, (Sample), Matrix. This is described by M. Schubert in the context of "Generalized Ellipsometry", (see Background Section for citations to relevant articles which treat the topic of Generalized ellipsometry by Schubert).

If an ideal Compensator is assumed, where the Jones Matrix components are:

$$\begin{aligned}r_1 &= 1; \\r_2 &= 0; \\r_3 &= 0; \text{ and} \\r_4 &= e^{i\delta};\end{aligned}$$

then the Eqs. 9 become Eqs. 10 - 14:

$$DC = (1/2) (1 + \cos \delta) [\cos 2A (\cos 2P - \cos 2\Psi) + \sin 2A \sin 2P \sin 2\Psi \cos \Delta] - \cos 2P \cos 2\Psi + 1 \quad (10)$$

$$\alpha_2 = -\sin 2A \sin 2P \sin \delta \sin 2\Psi \sin \Delta \quad (11)$$

$$\beta_2 = \cos 2A \sin 2P \sin \delta \sin 2\Psi \sin \Delta \quad (12)$$

$$\alpha_4 = (1/2) (1 - \cos \delta) [\cos 2A (\cos 2P - \cos 2\Psi) - \sin 2A \sin 2P \sin 2\Psi \cos \Delta] \quad (13)$$

$$\beta_4 = (1/2) (1 - \cos \delta) [\sin 2A (\cos 2P - \cos 2\Psi) + \cos 2A \sin 2P \sin 2\Psi \cos \Delta] \quad (14)$$

It is noted that said Eqs. 10 - 14 are found in Kleim et al. as referenced in the Background Section of this Specification, with "A" and "P" interchanged. (The Kleim et al. work assumed a Rotating Compensator present prior to a Material System, (Sample)).

Continuing, Eqs. 10 - 14 are valid for an ideal Rotating Compensator System wherein the Azimuthal angles of the optics are perfectly aligned with the Material System, (Sample), frame of reference. In practice this is never true, and offset terms "A'", "P'" and "C'" must be entered to provide Eqs. 15a and 15b:

$$A = A' - A_s, \quad P = P' - P_s \quad (15a)$$

$$C = C' - C_s \quad (15b)$$

where the A' , C' and P' indicate dial readings and the A_s , C_s and P_s indicate Offset Angles to be determined by a Calibration Procedure.

Substituting Eq. 15b into Eq. 8 provides Eqs. 16a and 16b, and 17a and 17b for Fourier Coefficients, (note that the DC term is unchanged):

$$m\alpha_2 = \alpha_2 \cos 2C_s - \beta_2 \sin 2C_s \quad (16a)$$

$$m\beta_2 = \alpha_2 \sin 2C_s + \beta_2 \cos 2C_s \quad (16b)$$

$$m\alpha_4 = \alpha_4 \cos 4C_s - \beta_4 \sin 4C_s \quad (17a)$$

$$m\beta_4 = \alpha_4 \sin 4C_s + \beta_4 \cos 4C_s \quad (17b)$$

Continuing, the disclosed invention simultaneously measures the Intensity, (any functionally similar magnitude to be considered equivalent for the purposes of this disclosure), vs. time or compensator rotation angle of a multiplicity of essentially single wavelengths with a Photo Array, to determine Fourier Coefficients. And as the Diode Elements in the Photo Array are operated in a Charge Integration Mode, it is necessary to utilize a Hadamard analysis of the signal. In the embodiment of the invention disclosed in the Parent Patent 5,872,630, the Diode Array was disclosed as synchronously read-out exactly sixteen (16) times during each rotation of the Rotating Compensator. (See supra herein wherein it is reported that presently preferred practice is to read-out a photo-array an odd number, (eg. thirteen (13) times),

during each rotation of the Rotating Compensator). The time varying signal, which results from modulation imposed by the Rotating Compensator, is given by Eq. 18. Eq. 19 represents a measured value at a given channel in a Photo Array for the i'th scan measured during the rotation.

$$s(t) = I_0 \cdot (DC + \alpha_2 \cos 2t + \beta_2 \sin 2t + \alpha_4 \cos 4t + \beta_4 \sin 4t) \quad (18)$$

$$h_i = \int_{(i-1) \cdot \frac{\pi}{8}}^{i \cdot \frac{\pi}{8}} s(t) dt \quad (19)$$

Substituting Eq. 18 into Eq. 19 and rearranging terms provides the following expressions, (Eqs. 20 - 24), for the Fourier Coefficients:

$$DC = \frac{h_1 + h_2 + h_3 + h_4 + h_5 + h_6 + h_7 + h_8 + h_9 + h_{10} + h_{11} + h_{12} + h_{13} + h_{14} + h_{15} + h_{16}}{4 \cdot I_0} \quad (20)$$

$$\alpha_2 = \frac{h_1 + h_2 - h_3 - h_4 - h_5 - h_6 + h_7 + h_8 + h_9 + h_{10} - h_{11} - h_{12} - h_{13} - h_{14} + h_{15} + h_{16}}{8 \cdot I_0} \quad (21)$$

$$\beta_2 = \frac{h_1 + h_2 + h_3 + h_4 - h_5 - h_6 - h_7 - h_8 + h_9 + h_{10} + h_{11} + h_{12} - h_{13} - h_{14} - h_{15} - h_{16}}{8 \cdot I_0} \quad (22)$$

$$\alpha_4 = \frac{h_1 - h_2 - h_3 + h_4 + h_5 - h_6 - h_7 + h_8 + h_9 - h_{10} - h_{11} + h_{12} + h_{13} - h_{14} - h_{15} + h_{16}}{8 \cdot I_0} \quad (23)$$

$$\beta_4 = \frac{h_1 + h_2 - h_3 - h_4 + h_5 + h_6 - h_7 - h_8 + h_9 + h_{10} - h_{11} - h_{12} + h_{13} + h_{14} - h_{15} - h_{16}}{8 \cdot I_0} \quad (24)$$

Equations 20 - 24 provide means for extracting the Fourier Coefficients for the Rotating Compensator modulated signal from the (h_i) values which are measured by the Photo Array Diode Elements during continuous rotation of the Rotating Compensator.

The foregoing Eqns. 18-24, and associated text, provides disclosure regarding application of Hadamard Analysis in Parent Patent No. 5,872,630. At this point, regarding Hadamard Analysis, it is disclosed that since said 630 Patent disclosure was formulated, additional work has provided insight to a method for determining Hadamard Coefficients for an arbitrary "n"-point Hadamard Transform. It is noted that current practice is to select "n" to be an odd number of at least nine (9), (rather than the previously recited value of sixteen (16)), and preferably thirteen (13). This allows accounting for not only D.C. and even harmonics, (eg. second (2nd) and forth (4th) which appear in invention output signals), but also for odd harmonics (eg. fifth (5th) and seventh (7th)), and the results of electronics non-linearities. In any case, it is emphasized that preferred practice teaches that "n" should be selected to be an odd number.

Continuing, disclosed invention practice provides that that for a given sampling period, application of the Hadamard analysis leads to calculation of the D.C. Signal Intensity, plus Sin and Cos Terms at $(n-1)/2$ harmonic frequencies. Consider that all measured points are indexed by a variable "i", while "ic" and "is" index the Cos and Sin components, respectively, and "j" indexes harmonic frequency components.

Consider, for $(n = 9)$:

$$i = 0 \dots n-1;$$

$$\begin{aligned} ic &= 1, 3 \dots n-1 \\ is &= 2, 4 \dots n-1; \end{aligned}$$

$$j = 0 \dots \frac{(n-1)}{2}$$

Sin and Cos Basis Functions are piecewise integrated using Hadamard Formalism. The resulting Coefficients are then packed into a Square Matrix denoted "M", as indicated in Eqs. 19':

$$hc(i, j) := \int_{\frac{2\pi}{n} \cdot i}^{\frac{2\pi}{n} \cdot (i+1)} \cos(j \cdot t) dt \quad hs(i, j) := \int_{\frac{2\pi}{n} \cdot i}^{\frac{2\pi}{n} \cdot (i+1)} \sin(j \cdot t) dt \quad 19'$$

$$M_{i,0} := hc(i, 0) \quad M_{i,ic} := hc\left(i, \text{floor}\left(\frac{ic}{2}\right) + 1\right) \quad M_{i,is} := hs\left(i, \text{floor}\left(\frac{is}{2}\right)\right)$$

The "M" Matrix is then inverted, yielding

$$H := M^{-1}$$

a Matrix of Coefficients "H" which can be applied to a general n-point data system stream to evaluate the "n" frequency components, ((D.C. + Sin + Cos terms at (n-1)/2 frequencies).

To extract the Eq. 18 frequency components of s(t), the signal is piecewise integrated, the resulting coefficients stored in "h", and multiplied times the Hadamard Coefficient Matrix "H", as indicated in Eqs. labeled 20' - 24' below:

As an example, consider the signal 's(t)' below which contains a DC value of 2.5, a 2nd harmonic 'cos' term of -6.1, and a 4th harmonic 'sin' term of 1.4.

$$s(t) := 2.5 + -6.1 \cdot \cos(2 \cdot t) + 1.4 \cdot \sin(4 \cdot t)$$

To extract the frequency components of s(t), the signal is piecewise integrated (the resulting coefficients are stored in 'h'), and multiplied times the Hadamard coefficient matrix 'H'.

$$h_i = \int_{\frac{2\pi}{n} \cdot i}^{\frac{2\pi}{n} \cdot (i+1)} s(t) dt$$

2.5	DC component	20' - 24'
0	1st harmonic, 'cos' component	
0	1st harmonic, 'sin' component	
-6.1	2nd harmonic, 'cos' component	
0	2nd harmonic, 'sin' component	
0	3rd harmonic, 'cos' component	
0	3rd harmonic, 'sin' component	
0	4th harmonic, 'cos' component	
1.4	4th harmonic, 'sin' component	

As in the 630 Parent Patent, it is generally emphasized that good quality electronics which employ the Video Integration Read-Out technique have been found to be very conducive to accurately measuring Fourier Coefficients using Photo Array Diode Elements. It is to be understood that said good quality electronics interface output signals from Photo Array Diode Elements to a computer system which collects and analyzes data. Preferred "Off-The-Shelf-Systems" which include good quality electronics, suitable for use in the disclosed invention Rotating Compensator Material System Investigation System, are Zeiss, (Trademark), Diode Array Spectrometer systems identified by manufacturer numbers selected from the group: MMS1 (300-1150 nm); UV/VIS MMS (190-730 nm); UV MMS (190-400 nm); AND IR MMS (900-2400 nm). Said Zeiss systems also include Dispersive Optics and Diode Element containing Photo Arrays. The Zeiss systems include fourteen (14) bit dynamic range readout electronics, which provides a voltage pulse output. The disclosed invention system provides additional good-quality electronics in the form of an integrator and Analog to Digital Converter. In use, the scanning rate of Diode Elements in a Zeiss system Photo Array is synchronized with the rotation of the Rotating Compensator of the disclosed invention Rotating Compensator Material System Investigation System. Said synchronization is accomplished utilizing standard digital logic, and Diode Elements in the Photo Array are scanned sixteen (16) times under previous practice, and thirteen (13) times

under present practice, during each rotation of the Rotating Compensator. It is further noted that the disclosed invention preferably effects rotation of the Rotating Compensator with a hollow shaft Stepper Motor. While it is possible to sense pulses from a sensor attached to a rotating compensator, and use said pulses to synchronize detector output, a preferred approach provides that a sequence of reference pulses is simultaneously provided to the Stepper Motor and to Photo Array Diode Elements. Said reference pulses allow correlation of the angular position of the Rotating Compensator with data provided by the Scanned Photo Array Diode Elements. Further, a phase sensor operates like a traditional encoder, but it is not necessary to trigger off its digital output. Instead the phase sensor output and detector array data are stored and subsequent processing used to determine the phase of the stepper motor, which directly relates to the azimuthal orientation of the rotating compensator.

Regarding Photo Array data, it is further noted that authors, An and Collins, describe some of the non-idealities which can be present when using a Photo Array Detector in a Spectroscopic Rotating Compensator Material System Investigation System. With the exception of the An and Collins correction for "Stray Light" (see An and Collins Eq. 13), however, none of the Photo Array non-ideality corrections which were presented in their paper were found necessary in implementing the preferred embodiment of the disclosed invention. However, to allow a non-ideal Photo Array to be used in the disclosed invention, the relevant corrections for a Image Persistence, and for Read Time in a Spectroscopic Rotating Compensator Material System Investigation System in which sixteen (16) Diode Element Scans are acquired for each Rotating Compensator revolution were derived, and are provided in Eqs. 25 - 34.

Image Persistence correction, where 'x' is the magnitude of the non-ideality:

$$ip\alpha_2 = \alpha_2 - .5 \cdot x \left[(2 - \sqrt{2}) \cdot \alpha_2 + \sqrt{2} \cdot \beta_2 \right] \quad (25)$$

$$ip\beta_2 = \beta_2 - .5 \cdot x \cdot \left[(2 - \sqrt{2}) \cdot \beta_2 - \sqrt{2} \cdot \alpha_2 \right] \quad (26)$$

$$ip\alpha_4 = \alpha_4 - x \cdot (\alpha_4 + \beta_4) \quad (27)$$

$$ip\beta_4 = \beta_4 - x \cdot (\beta_4 - \alpha_4) \quad (28)$$

$$ipDC = DC \quad (29)$$

Read Time correction, where 'p' is the channel read time of the diode array:

$$c\alpha_2 = ip\alpha_2 - .5 \cdot p \cdot \left[(1 + \sqrt{2}) \cdot ip\alpha_2 + ip\beta_2 \right] \quad (30)$$

$$c\beta_2 = ip\beta_2 - .5 \cdot p \cdot \left[(1 + \sqrt{2}) \cdot ip\beta_2 - ip\alpha_2 \right] \quad (31)$$

$$c\alpha_4 = ip\alpha_4 - p \cdot (ip\alpha_4 + ip\beta_4) \quad (32)$$

$$c\beta_4 = ip\beta_4 + p \cdot (ip\alpha_4 - ip\beta_4) \quad (33)$$

$$cDC = \left(1 - \frac{4 \cdot p}{\pi} \right) \cdot ipDC \quad (34)$$

Eqs. 25 - 34 can be applied after Eqs. 10 - 17 to account for non-idealities in the Photo Array Diode Element readout. The Image Persistence and Read-Out non-ideality factors 'x' and 'p' can also be determined by defining them as Fit Parameters in a Calibration Regression procedure presented in the following section of this Specification.

For demonstration purposes, considering now the disclosed invention Spectroscopic Rotating Compensator Material System Investigation System to be a Rotating Compensator Ellipsometer System with Diode Element Array read-out, it must be understood that to acquire usable data, Calibration must be performed. Said calibration provides numerical values for Azimuthal Orientation Off-set Angles of Polarizer, Analyzer and

Compensator with respect to a Material System, (Sample), Frame
of Reference, along with the Retardance of the Rotating
Compensator as a function of Wavelength. In addition,
Calibration Parameters to compensate non-idealities in Diode
Elements in a Photo Array are calibrated.

The foundation of the Calibration Procedure was first
announced in the 1993 paper by Johs, published in Thin Film
Solids, cited in the Background Section herein. The same basic
Calibration Procedure technique is further developed in Patent
5,706,212 which describes calibration of a Rotating Compensator
Ellipsometer System utilized in the Infra-red (IR) band of
wavelengths. Both identified references, however, describe
typical application of the Regression based Calibration
technique to one (1) wavelength at a time. While this method
does work, it can require two-hundred-fifty-six (256) sets of
Calibration Parameters where a two-hundred-fifty-six (256) Diode
Element Photo Array is utilized, with each Diode Element serving
to monitor an essentially single wavelength. (Note, as the
electromagnetic spectrum is continuous, an essentially single
wavelength is to be understood to be a small range of
wavelengths centered around some wavelength, which essentially
single wavelength is intercepted by a Diode Element in a Photo
Array).

In practice of the disclosed invention a "Global"
regression procedure is typically performed on a Two (2)
Dimensional Data Set. Typically Polarizer Azimuthal Angle and
Wavelength are selected as Data Set Independent variables,
although electromagnetic beam Angle-of-Incidence with respect to
a Material System, (Sample), surface could be selected as an
Independent variable instead of, for instance, Wavelength or
Polarizer Azimuthal Angle. It is also noted that the
Regression based Calibration described in Patent No. 5,706,212
required that two (2), at least two (2) Dimensional Data Sets be

provided in each Regression procedure. The two Data Sets are obtained with different investigated Material System, (Sample), configurations being employed. For instance, Data Sets utilizing two different Material Systems, (Samples), or one
5 Material System, (Sample), present and a "Straight-through" configuration might be utilized. (Note, a "Straight-through" configuration results when no Material System, (Sample), is present, and an electromagnetic beam is caused to pass sequentially through a Polarizer, Compensator and Analyzer then
10 enter a Photo Array Detector System, without interacting with a Material System, (Sample)). The disclosed invention, in its most basic embodiment, requires that only one Data Set be present. Said Data Set can be obtained with the Ellipsometer in Material System, (Sample), present or Straight-through
15 configuration, although some benefits are realized when a Material System, (Sample), is utilized, (discussed supra herein). Of course, the disclosed invention can be practiced utilizing Multiple-Data Sets.

20 As mentioned, the Regression based Calibration procedure of the disclosed invention requires that an at least Two (2) Dimensional Data Set be experimentally obtained. Typically said Two (2) Dimensional Data Set has as Independent Variables, Polarizer, (where the Rotating Compensator is placed after a
25 Material System, (Sample)), Azimuthal Angle, and Wavelength. Where a Rotating Compensator is placed before a Material System, (Sample), an Analyzer Azimuthal Angle is typically utilized. As mentioned, Angle-of-Incidence of an investigation Electromagnetic Beam with respect to an investigated Material
30 System, (Sample), surface can be substituted for an Analyzer or Polarizer Azimuthal Angle settings, but this is not preferred as Material System, (Sample), PSI and DELTA values vary therewith. Also, it is generally simpler to vary a Polarizer or Analyzer Azimuthal Angle in most Ellipsometer systems in

practice. Continuing, data is simultaneously obtained from many Diode Elements, (which correspond to different Wavelengths), and subjected to the Hadamard analysis inherent in Eqs. 20 - 24, infra, (and see also Eqs. 20' - 24' supra herein), to provide Fourier Coefficients present in Eq. 18. (It is noted that a Photo Array can contain 256, 1024 or 2048 Diode Elements, and some thereof might provide a signal which of too small an intensity to be utilized. The disclosed invention allows for utilizing only a user selected group of signals for this and other reasons).

It will be noted that Eqs. 8 and 18 contain a D.C. term "I₀". This can be selected as a Fit Parameter in a Regression Procedure or a Normalization procedure can be implemented. Said Normalization can be with respect to the D.C. term, or a Normalizing Parameter can be included. The following Eqs 35a, 35b and 35c provide possible Normalizing Parameters:

$$\text{Norm} = \text{DC} \quad (35a)$$

$$\text{Norm} = \sqrt{(\alpha_2)^2 + (\beta_2)^2 + (\alpha_4)^2 + (\beta_4)^2 + (\text{DC})^2} \quad (35b)$$

$$\text{or} \\ \text{Norm} = \sqrt{(\alpha_2)^2 + (\beta_2)^2 + (\alpha_4)^2 + (\beta_4)^2} \quad (35c)$$

Eq. 35a provides for Normalizing with respect to the D.C. term, Eq. 35b provides for Normalizing to a Parameter which depends on the D.C. Term and the Fourier Coefficients, while Eq. 35c provides for Normalizing to a Parameter which depends on Fourier Coefficients but not the D.C. Term. If Fourier Coefficients are not Normalized, (ie. the D.C. Term "I₀" is not included as a Fit Parameter in a Calibration Parameter evaluating Regression Procedure, or Normalization is not performed), it should be

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appreciated that a "Floating" value result will be obtained for Calibration Parameters provided by application of the Calibration Parameter evaluating Regression onto said Fourier Series Coefficient values. As mentioned infra herein, the D.C. Component " I_0 " can be difficult to evaluate, often requiring a "Shutter" to block background light, dark current, readout electronics voltage offsets etc. As well, the D.C. component is more susceptible to instrumentation drift. As a result, use of Eq. 35c can be preferable in the disclosed invention Calibration Procedure to use of Eqs. 35a and 35b and to including " I_0 " in a Regression Procedure for evaluating Calibration Parameters. (Note that calibration data is taken with the Rotating Compensator Sample System Investigating System in a "Sample Present", rather than a "Straight Through" configuration, where such Eq. 35c normalization is practiced). (Note, Eqs. 67, and accompanying discussion, provide additional insight to Calibration Normalization).

It is further noted that recent practice has adopted use of multiple data sets, similar to that described in Patent No. 5,706,212 in disclosed invention procedures to calibrate a Rotating Compensator System, where it is desired to evaluate not only Ellipsometric Parameters, but Depolarization/Mueller Matrix values as well. Said multiple data sets can be obtained with different samples in place and/or with the ellipsometer system in a "straight-through" configuration. It is disclosed that it has been found desirable to normalize data to D.C. in some portions of calibration, and to an A.C. derived term in other portions thereof. An equation, such as presented in EQ. 35c, (which is derived from Fourier Coefficients), is an example of an A.C. data normalization parameter.

To shed light as to why various use of D.C. and A.C. based data normalization Parameters is beneficial, the following

parameters are defined:

$$\begin{aligned}N &= \cos (2*PSI); \\C &= \sin (2*PSI) \cos (\Delta); \text{ and} \\S &= \sin (2*PSI) \sin (\Delta).\end{aligned}$$

Further:

$$\begin{aligned}C &= (fc(\alpha_2, \beta_2, \alpha_4, \beta_4))/D.C.; \\S &= (fs(\alpha_2, \beta_2, \alpha_4, \beta_4))/D.C.; \\N &= (fn(\alpha_2, \beta_2, \alpha_4, \beta_4))/D.C.;\end{aligned}$$

(where fc , fs and fn are functions to extract N , C and S from α_2 , β_2 , α_4 , β_4 AND D.C.); and

$$\tan (\Delta) = S/C, \text{ (note the D.C. term cancels);}$$

$$\begin{aligned}\tan (PSI) &= ((C^2 + S^2)^{1/2})/N, \\&\text{(note the D.C.term cancels);}\end{aligned}$$

$$\%DEPOL = 100\%(1 - N^2 - C^2 - S^2).$$

Thus it is demonstrated that PSI and Δ can be calculated without the requirement of a D.C. term, but that calculation of Depolarization require knowledge of the D.C. term.

Preferred calibration procedure practice provides that data be normalized to an A.C. derived basis, (eg. EQ. 35c), when determining such as compensator retardation (R), polarizer azimuth (P) and compensator fast axis azimuth (C), and that data be normalized to D.C., (eg. EQ. 35a or 35b), where optical element Depolarization/Mueller Matrix values are fit. Thus a calibration procedure as recited infra herein can be modified to include a step in which an appropriate normalization basis is

determined at various steps therein.

(Note, in Eqs. 67, a different approach to defining Depolarization is presented. Nonideality Depolarization terms identified as 'b' and 'c' appear only in a D.C. term.)

Where data normalization by D.C., or A.C, or a combination of D.C. and A.C. normalization data bases is practiced, the method of calibrating the spectroscopic rotating compensator material system investigation system can, in terminology similar to that in the 630 Patent, be recited as comprising, in any functional order, the steps of:

STEP A.

Providing a spectroscopic rotating compensator material system (sample) investigation system comprising a source of a polychromatic beam of electromagnetic radiation, a polarizer means, a stage for supporting a material system (sample), an analyzer means, a dispersive optics and at least one detector system which contains a multiplicity of detector elements, said spectroscopic rotating compensator material system investigation system further comprising at least one compensator(s) means positioned at a location selected from the group consisting of: (before said stage for supporting a material system, and after said stage for supporting a material system, and both before and after said stage for supporting a material system (sample)); such that when said spectroscopic rotating compensator material system investigation system is used to investigate a material system (sample) present on said stage for supporting a material system, said analyzer means and polarizer means are maintained essentially fixed in position and at least one of said at least one compensator(s) means is/are caused to

continuously rotate while a polychromatic beam of electromagnetic radiation produced by said source of a polychromatic beam of electromagnetic radiation is caused to pass through said polarizer means and said compensator(s) means, said polychromatic beam of electromagnetic radiation being also caused to interact with said material system (sample), pass through said analyzer means and interact with said dispersive optics such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements in said at least one detector system;

at least one of said at least one compensator(s) means preferably being a selection from the group consisting of:

comprised of a combination of at least two zero-order waveplates, said zero-order waveplates having their respective fast axes rotated to a position offset from zero or ninety degrees with respect to one another;

comprised of a combination of at least a first and a second effective zero-order wave plate, said first effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes of the multiple order waveplates in said second effective zero-order wave plate being rotated to a position at a nominal forty-five degrees to the fast axes, respectively, of the multiple order waveplates in said first effective zero-order waveplate;

comprised of a combination of at least a first and a second effective zero-order wave plate, said first effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes of the multiple order waveplates in said second effective zero-order wave plate being rotated to a position away from zero or ninety degrees with respect to the fast axes, respectively, of the multiple order waveplates in said first effective zero-order waveplate;

comprised a combination of at least one zero-order waveplate and at least one effective zero-order waveplate, said effective zero-order wave plate being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, the fast axes of the multiple order waveplates in said effective zero-order wave plate being rotated to a position away from zero or ninety degrees with respect to the fast axis of the zero-order waveplate;

STEP B.

developing a mathematical model which comprises as calibration parameter variables such as polarizer means azimuthal angle orientation, present material system (sample) PSI, present material system (sample) DELTA, compensator means azimuthal angle orientation(s), matrix components of said

compensator(s) means , and analyzer means azimuthal angle orientation, which mathematical model is effectively a transfer function which enables calculation of electromagnetic beam magnitude as a function of wavelength detected by a detector element, given magnitude as a function of wavelength provided by said source of a polychromatic beam of electromagnetic radiation;

STEP C.

causing a polychromatic beam of electromagnetic radiation produced by said broadband electromagnetic radiation source means of a polychromatic beam of electromagnetic radiation, to pass through said polarizer means, interact with a material system (sample) caused to be in the path thereof, pass through said analyzer means, and interact with said dispersive optics such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements in said at least one detector system, with said polychromatic beam of electromagnetic radiation also being caused to pass through said compensator(s) means positioned at a location selected from the group consisting of: (before said stage for supporting a material system, and after said stage for supporting a material system, and both before and after said stage for supporting a material system);

STEP D.

obtaining at least one, multi-dimensional, data set of magnitude values vs. wavelength and at least one parameter selected from the group consisting of:

angle-of-incidence of said polychromatic beam of electromagnetic radiation with respect to a present material system; and

azimuthal angle rotation of one element
selected from the group consisting of:

said polarizer means;

5 said analyzer means;

OR

10 obtaining at least one multi-dimensional data set or at
least two, at least one-dimensional, data sets of magnitude
values vs. parameter(s) selected from the group consisting of:

wavelength;

15 angle-of-incidence of said polychromatic
beam of electromagnetic radiation with
respect to a present material system; and

20 azimuthal angle rotation of one element
selected from the group consisting of:

said polarizer means; and

25 said analyzer means;

over time, while at least one of said at least one
compensator(s) is caused to continuously rotate;

30 (It is noted here that a Reference Material System,
(Sample), Thickness, or the Thickness of a Surface
Layer thereupon, as well as DELTA Offset resulting
from electromagnetic beam passage through

birefringent window(s) and/or lens(es), or wavelength shifts can be utilized as additional parameterization independent variables)

5 said data set(s) being obtained utilizing a selection from the group consisting of:

10 all of said data set(s), being obtained with a single material system placed on said stage for supporting a material system, with which material system said beam of electromagnetic radiation is caused to interact;

15 at least one of said data set(s), being obtained utilizing one material system placed on said stage for supporting a material system, with another of said data set(s), being obtained utilizing another material system (sample) placed on said stage for supporting a material system (sample), with which material system (sample) said beam of electromagnetic radiation is caused to interact; and

20 at least one of said data set(s) being obtained with the spectroscopic rotating compensator material system (sample) investigation system oriented in a "straight-through" configuration wherein a polychromatic beam of electromagnetic radiation produced by said source of a polychromatic beam of electromagnetic radiation, is caused to pass through said polarizer means, pass through said analyzer means and interact with said dispersive optics such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements in said at least one detector system, with said polychromatic beam of electromagnetic radiation also being caused to pass through at least one compensator(s) means but without being caused to interact with any material system

25

30

(sample) placed on said stage for supporting a material system (sample) other than open ambient atmosphere;

STEP E.

normalizing data in said data set(s) with respect to a selection from the group consisting of:

a data set D.C. component;

a data set A.C. component;

a parameter derived from a combinations of a data set D.C. component and a data set A.C. component;

STEP F.

performing a mathematical regression of said mathematical model onto said normalized data set(s) thereby evaluating calibration parameters in said mathematical model;

said regression based calibration procedure serving to evaluate parameters in said said mathematical model for non-achromatic characteristics and/or non-idealities and/or positions of at least one selection from the group consisting of:

azimuthal angle of said polarizer means;

retardation of said compensator(s) means ;

azimuthal angle(s) of said compensator(s) means, and

depolarization/Mueller Matrix

components.

azimuthal angle of said analyzer means.

5

STEP G.

optionally repeating STEPS E. and F. utilizing a different selection in STEP E. in normalizing data.

10 (Note that optionally un-normalized D.C. and/or A.C. data can be utilized to determine Reflectance and said information utilized in determining parameter values in the Step F. Regression. Further, once Calibration is completed, parameter values other than Sample characterizing parameters can be fixed, and
15 additional Samples investigated with only Sample Characterizing Parameters being left for evaluation).

Continuing, normalized Fourier Coefficients can be
20 represented by Eqs 36 - 39:

$$n\alpha_2 = \frac{\alpha_2}{\text{Norm}} \quad (36)$$

$$n\beta_2 = \frac{\beta_2}{\text{Norm}} \quad (37)$$

$$n\alpha_4 = \frac{\alpha_4}{\text{Norm}} \quad (38)$$

$$n\beta_4 = \frac{\beta_4}{\text{Norm}} \quad (39)$$

30 A Global Calibration Data Set can be represented by Eq. 40:

$$\text{MFD}_{P,n} = \{ (n\alpha_2)_{P,n}, (n\beta_2)_{P,n}, (n\alpha_4)_{P,n}, (n\beta_4)_{P,n} \} \quad (40)$$

where MFD stands for Masured Fourier Data, and where "P" is the Polarizer Angle and constitutes one Independent Variable, (and is typically varied within the range of from zero (0.0) to one-hundred-eighty (180) degrees, in ten (10) degree steps), and where "n" identifies the index of a selected Diode element, (channel), in the Photo Array, or alternatively stated, identifies a Second Independent Variable, (ie. Wavelength). It is noted that a typical system configuration would make use of Diode Elements (channels) 30 - 250 in a 256 channel Photo Array. The term "Global" emphasizes the presence of Wavelength Dependence. Utilizing the just described "P" range settings and Wavelength range, Eq. 41 indicates that the Global MFD Data Set would contain:

$$(180/10 + 1 \text{ polarizer settings}) \times (250 - 30 + 1 \text{ channels}) \times (4 \text{ Fourier components}) = 16,796 \text{ values} \quad (41)$$

It is further noted that an approximate error in Fourier Data can be estimated from signal to noise at each Detector Channel, and subsequently used in the Regression Analysis of the Experimentally Obtained Data Set.

Continuing, use of Eqs. 3 - 17, 35 - 39 and (25 - 34 if Photo Array non-idealities are included), allows one to calculate, (ie. mathematically predict), values of Normalized Fourier Coefficients as in Eqs. 36 - 39, which will be experimentally measured by a Rotating Compensator Material System Investigation System. However, to make said mathematical prediction requires that Material System, (Sample), PSI and DELTA values be known, the Offset Angles P_s , A_s , and C_s be known, and that Compensator Retardation " δ " be known as well as any other Compensator non-idealities, and that the Photo Array non-idealities " x " and " ρ " be known if necessary. Mathematically this can be represented by Eq. 42:

$$PFD_{P,n}(P, \Psi_n, \Delta_n, (P_s)_n, (C_s)_n, (A_s)_n, \delta_n, x_n, \rho_n) \quad (42)$$

Eq. 42 states that a Predicted Fourier Data (PFD) Set at a given Polarizer Azimuth and Photo Array Channel (Wavelength), is a function of identified variables, which variables constitute Calibration Parameters which must be provided numerical values. The Regression procedure provides means for numerically evaluating the Calibration Parameters.

In all known prior art, separate Regression procedures have been carried out at each utilized Wavelength. If Two-Hundred (200) Wavelengths were utilized, then Two-Hundred (200) separate values for P_s , A_s and C_s etc. would be obtained. The Regression Procedure, however, teaches that Calibration Parameters as a function of an Independent Variable, (eg. Wavelength), can be "Parameterized". That is, a mathematical relationship requiring only a few (eg. perhaps two (2) or three (3) Parameters), can be generated to describe a functional relationship between the Calibration Parameter and the Independent Variable (eg. Wavelength), and the Regression Procedure utilized to evaluate said Two (2) or Three (3) Parameters. For example, the Polarizer Azimuthal Offset (P_s) might be constant for all Wavelengths. Should this be the case then said Polarizer Azimuthal Offset (P_s) can be evaluated and stored, rather than, for instance, Two-Hundred (200) separate values at Two-Hundred (200) separate Wavelengths. In this instance, Eq. 43 indicates that a Global Calibration Parameter can be defined:

$$(P_s)_n = gP_s \quad (43)$$

In general, any of the discretely defined Calibration Parameters identified in Eq. 42, could be replaced by a Global Parametric Function as defined in Eq. 44:

$$CP_n = gCP(n, p_1, p_2, \dots, p_k) \quad (44)$$

where CP_n stands for any Calibration Parameter which is

discretely defined for each "n"'th channel, (ie. the "n"'th Wavelength), and "gCP" is a global Parametric Function (as a function of an "n"'th channel number and "k" Calibration Parameters "p1...pk) which replace CP_n . A Parametric Function can be of any mathematical form, such as, but not limited to, polynomial, rational or transcendental (in the case of Ψ_n and Δ_n , a Parametric Function could be calculated from a multi-layer optical model for a Material System, (Sample), using known Material Optical Constants and Parameterized Film Thicknesses). The important characteristic of a Parametric Function being that:

1. It accurately represents the behavior of the Calibration Parameter at each Independent Variable (eg. Photo Array Channel or Wavelength).

2. It accurately represents the behavior of the Calibration Parameter utilizing fewer Parameters than would be required to simply evaluate Calibration Parameters at each utilized Independent Variable (eg. Wavelength).

In terms of Eq. 44 this can be stated that "k" (the number of Calibration Parameters), is less than "n" (the number of channels).

It is to be understood that preferred Global Parameter Function form utilized depends upon the particular embodiment utilized, (eg. the Compensator type utilized). It is also within the scope of the Regression based Calibration Parameter evaluation Procedure to represent some Calibration Parameters with Global Parametric Functions, and to represent other Calibration Parameters discretely. Three examples of Global Parametric Function utilizing Models follow directly.

Global Regression Mode (GRM) 1.

This (GRM) requires that five (5) Calibration Parameters be evaluated. Eqs. 45 - 47 provide equations for Predicted Fourier Data (PFD):

$$\text{PFD}_{P,n}(P, \Psi_n, \Delta_n, gP_s, gC_s, gA_s, g\delta(n, p_0, p_1)) \quad (45)$$

$$\text{where } g\delta(n, p_0, p_1) = [p_0 \cdot 90 \cdot (1 + p_1 / [w(n)]^2)] / w(n) \quad (46)$$

$$\text{and } w(n) = C_0 + C_1 \cdot n + C_2 \cdot n^2 \quad (47)$$

where $w(n)$ returns a wavelength of electromagnetic radiation (in nanometers), corresponding to the "n" 'th channel of a Photo Array, where C_0 , C_1 and C_2 are wavelength Calibration Parameters. In the case where a previously identified Ziess Diode Array Spectrometer Systems is utilized, said C_0 , C_1 and C_2 Calibration Parameters are provided by the manufacturer, and Eq. 47 can be utilized to provide Wavelength given a Photo Array Channel number. The Global Retardance provided by a Compensator as a function of Wavelength is given by Eq. 46. Eq. 46 provides an Inverse Wavelength relationship, where " p_0 " is a Wavelength, (in nanometers), at which said Compensator is a "Quarter-Wave-Plate" and demonstrates a Ninety (90) degree Retardation, and " p_1 " accounts for the Dispersive effects in the Optical Properties of the Compensator. Higher order terms can be added to Eq. 46.

In this (GRM) Mode 1, the Azimuthal Offset Calibration Parameters are considered constant for all Wavelengths. Therefore, using (GRM) Mode 1, only Five (5) Global Calibration Parameters:

$$(gP_s, gC_s, gA_s, p_0, p_1)$$

in addition to Material System, (Sample), PSI and DELTA:

$$\Psi_n \text{ and } \Delta_n$$

need to be evaluated by a Regression Procedure.

GLOBAL REGRESSION MODE (GRM) 2.

This Mode is similar to (GRM) 1, but the P_i Calibration Parameter is defined as a Global Calibration Parameter, (ie. it is a constant independent of Photo Array Channel Number "n"). Again, the Retardance of the Compensator is Parameterized by Eqs. 46 and 47. Values for C_i and A_i are allowed to take on discrete values at each Photo Array Channel, however, Eq. 48 indicates the relationship:

$$PFD_{P,n}(P, \Psi_n, \Delta_n, gP_s, (C_s)_n, (A_s)_n, g\delta(n, p_0, p_1)) \quad (48)$$

GLOBAL REGRESSION MODE (GRM) 3.

In this (GRM) 3 Mode, only P_i is defined as a Global Parameter, and all other system Calibration Parameters are allowed to take on discrete values at each Photo Array Channel. Eq. 49 indicates this relationship:

$$PFD_{P,n}(P, \Psi_n, \Delta_n, gP_s, (C_s)_n, (A_s)_n, \delta_n) \quad (49)$$

(SEE ALSO GLOBAL REGRESSION MODE (GRM) 4) SUPRA HEREIN.

REGRESSION

The Methodology of Patent No. 5,872,630 evaluates the Calibration Parameters identified infra herein utilizing standard non-linear regression analysis. First a metric is defined by Eq. 50 to quantify Error between Calculated Predicted Fourier Data (PFD) and Experimentally Measured Fourier Data (MFD).

$$\chi^2 = \sum_P \sum_n \left(\frac{MFD_{P,n} - PFD(P,n,p_k)}{\sigma MFD_{P,n}} \right)^2 \quad (50)$$

Eq. 50 is a simplified way of stating that overall error between measured and predicted Calibration Data Sets is given by the squared difference between each measured and corresponding calculated predicted Fourier data, normalized by the approximate error at each measured data point ($\sigma_{MFD_{p,n}}$), and summed over all the Polarizer and Wavelength (Channel) setting values. Eq. 51 provides a more rigorous mathematical definition.

$$\chi^2 = \sum_p \sum_n \left[\frac{\left[(m\alpha_2)_{p,n} - p\alpha_2(p,n,p_k) \right]^2}{(\sigma\alpha_2)_{p,n}} + \frac{\left[(m\beta_2)_{p,n} - p\beta_2(p,n,p_k) \right]^2}{(\sigma\beta_2)_{p,n}} + \dots \right. \\ \left. + \frac{\left[(m\alpha_4)_{p,n} - p\alpha_4(p,n,p_k) \right]^2}{(\sigma\alpha_4)_{p,n}} + \frac{\left[(m\beta_4)_{p,n} - p\beta_4(p,n,p_k) \right]^2}{(\sigma\beta_4)_{p,n}} \right] \quad (51)$$

In Eqs. 50 and 51, p_k represents the "k" adjustable system Calibration Parameters required to calculate (PFD). The well known Marquardt-Levenberg non-linear Algorithm, as described in the Johs paper cited in the Background Section herein, can be used to iteratively adjust system Calibration Parameters p_k to minimize error.

It is noted that good initial values are required to practice Regression which converges rapidly. The disclosed invention practice obtains good starting values for use in the Global Regressions described, by performing a number of non-global Regressions at a multiplicity of discrete Wavelengths. The resulting ranges of values for the various Calibration Parameters then allows educated selection for Global Regression starting values.

It is also noted that Global Regression can be performed utilizing only data from every "N"'th Channel, (eg. every "N"'th Wavelength), to reduce required Regression procedure time to arrive at convergence. This approach to Regression is still to be considered as Global.

Once the Spectroscopic Rotating Compensator Material System Investigation System is calibrated, it is possible to take data from unknown samples therewith and obtain PSI and DELTA plots therefore. Kleim et al., describes equations for PSI (Ψ) and DELTA (Δ) and these equations are provided as Eq. 52 and 53 herein:

$$\tan(2\Psi) = \frac{\sqrt{(\alpha_2)^2 + (\beta_2)^2} \cdot \left(\frac{1 - \cos(\delta)}{\sin(\delta)} \right)^2 + 4(\beta_4 \cdot \cos(2P) - \alpha_4 \cdot \sin(2P))^2}{2(\alpha_4 \cdot \cos(2P) + \beta_4 \cdot \sin(2P))} \quad (52)$$

$$\tan(\Delta) = \left(\frac{1 - \cos(\delta)}{2 \cdot \sin(\delta)} \right) \cdot \frac{\alpha_2 \cdot \sin(2P) - \beta_2 \cdot \cos(2P)}{\alpha_4 \cdot \sin(2P) - \beta_4 \cdot \cos(2P)} \quad (53)$$

In these equations the Analyzer should be set to +/- 45 degrees. Also, prior to applying Eqs. 52 and 53 the measured Fourier Data should be transformed into "ideal" Fourier Data by application of Eqs. 15a, 15b, 16a, 16b, 17a and 17b as well as Eqs. 25 - 34. Kleim et al. also describes the advantages of performing a zone-averaged measurement in a Rotating Compensator System, (ie. averaging the PSI and DELTA extracted from measurements with the Analyzer A set to first, +45 Degrees, and second to -45 Degrees. This can be concurrently practiced with the described methodology to further improve the accuracy of data measurement.

It is also noted that an alternative approach to obtaining Material System, (Sample), PSI and DELTA characterizing data, is to perform a Calibration Procedure on a Spectroscopic Rotating Compensator Material System Investigation System in a

Sample Present Mode, with said Material System, (Sample), present therein.

5 NEW DERIVATION OF FREQUENCY COMPONENTS IN GENERAL ROTATING COMPENSATOR ELLIPSOMETER/POLARIMETERS SYTEMS AS FIRST PRESENTED IN CO-PENDING APPLICATION SERIAL NO. 09/496,011.

10 Since the just reviewed teachings from Parent Patent 5,872,630 were originally presented, additional work in the area has resulted in derivation of more generalized Equations which account for various frequency components which present in a Rotating Compensator ellipsometer or polarimeter system. Said derivation is based in application of general Mueller Matrix
15 representations for optical elements. Eq. 54 provides said general Meuller Matrix representation:

$$M = \begin{bmatrix} m_{11} & m_{12} & m_{13} & m_{14} \\ m_{21} & m_{22} & m_{23} & m_{24} \\ m_{31} & m_{32} & m_{33} & m_{34} \\ m_{41} & m_{42} & m_{43} & m_{44} \end{bmatrix} \quad 54$$

25 Additionally, Eq. 55 demonstrates application of Rotation Matrices which serve to account for differences in angular orientation, (ϕ) between a beam path coordinate system and an optical element coordinate system:

$$M_{rot} = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos(2\phi) & -\sin(2\phi) & 0 \\ 0 & \sin(2\phi) & \cos(2\phi) & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} m_{11} & m_{12} & m_{13} & m_{14} \\ m_{21} & m_{22} & m_{23} & m_{24} \\ m_{31} & m_{32} & m_{33} & m_{34} \\ m_{41} & m_{42} & m_{43} & m_{44} \end{bmatrix} \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos(2\phi) & \sin(2\phi) & 0 \\ 0 & -\sin(2\phi) & \cos(2\phi) & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix} \quad 55$$

Multiplying Eq. 55 through provivdes:

$$\begin{bmatrix}
 m11 & m12 \cdot c2\phi - m13 \cdot s2\phi & m12 \cdot s2\phi + m13 \cdot c2\phi & m14 \\
 c2\phi \cdot m21 - s2\phi \cdot m31 & c2\phi^2 \cdot m22 + s2\phi^2 \cdot m33 - s2\phi \cdot c2\phi \cdot (m23 + m32) & c2\phi^2 \cdot m23 - s2\phi^2 \cdot m32 + s2\phi \cdot c2\phi \cdot (m22 - m33) & c2\phi \cdot m24 - s2\phi \cdot m34 \\
 s2\phi \cdot m21 + c2\phi \cdot m31 & c2\phi^2 \cdot m32 - s2\phi^2 \cdot m23 + s2\phi \cdot c2\phi \cdot (m22 - m33) & c2\phi^2 \cdot m33 + s2\phi^2 \cdot m22 + s2\phi \cdot c2\phi \cdot (m23 + m32) & s2\phi \cdot m24 + c2\phi \cdot m34 \\
 m41 & m42 \cdot c2\phi - m43 \cdot s2\phi & m42 \cdot s2\phi + m43 \cdot c2\phi & m44
 \end{bmatrix}$$

56

where $c2\phi = \cos(2\phi)$ and $s2\phi = \sin(2\phi)$.

Now, if a general optical element is continuously rotated, the Matrix in Eq. 56 can be broken into a sum of matrices which describe each frequency component, (ie. via Fourier Coefficients), and Eq. 57 demonstrates this:

$$M_{rot} = DC + A2 \cdot \cos(2\phi) + B2 \cdot \sin(2\phi) + A4 \cdot \cos(4\phi) + B4 \cdot \sin(4\phi)$$

57

where:

$$\begin{aligned}
 DC &= \begin{bmatrix} m11 & 0 & 0 & m14 \\ 0 & \frac{m22 + m33}{2} & \frac{m23 - m32}{2} & 0 \\ 0 & \frac{m32 - m23}{2} & \frac{m22 + m33}{2} & 0 \\ m41 & 0 & 0 & m44 \end{bmatrix} & A2 &= \begin{bmatrix} 0 & m12 & m13 & 0 \\ m21 & 0 & 0 & m24 \\ m31 & 0 & 0 & m34 \\ 0 & m42 & m43 & 0 \end{bmatrix} & B2 &= \begin{bmatrix} 0 & -m13 & m12 & 0 \\ -m31 & 0 & 0 & -m34 \\ m21 & 0 & 0 & m24 \\ 0 & -m43 & m42 & 0 \end{bmatrix} \\
 A4 &= \begin{bmatrix} 0 & 0 & 0 & 0 \\ 0 & \frac{m22 - m33}{2} & \frac{m32 + m23}{2} & 0 \\ 0 & \frac{m32 + m23}{2} & \frac{m33 - m22}{2} & 0 \\ 0 & 0 & 0 & 0 \end{bmatrix} & B4 &= \begin{bmatrix} 0 & 0 & 0 & 0 \\ 0 & \frac{-m32 - m23}{2} & \frac{m22 - m33}{2} & 0 \\ 0 & \frac{m22 - m33}{2} & \frac{m32 + m23}{2} & 0 \\ 0 & 0 & 0 & 0 \end{bmatrix}
 \end{aligned}$$

58

The frequency content for an arbitrary rotating optical element placed into an optical system can thus be easily calculated by inserting the appropriate frequency content matrix into the product of the Mueller Matrices which mathematically represent the optical system. And it is noted that while rotating a general optical element produces only D.C. and even harmonics, (ie. 2nd and 4th harmonics relative to the rotation frequency), if the Mueller Matrix elements are not constant as a function of rotation angle, additional "odd", and higher order harmonics could also be generated.

Proceeding, assuming that an ellipsometer system consists of an input polarizer with azimuthal angle P, a general rotating element, an analyzer with an azimuthal angle A, and a detector, an equation for Intensity output from a General Rotating Element Ellipsometer System can be derived as follows:

$$I = \begin{pmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos(2A) & -\sin(2A) & 0 \\ 0 & \sin(2A) & \cos(2A) & 0 \\ 0 & 0 & 0 & 1 \end{pmatrix} \begin{pmatrix} 1 & 1 & 0 & 0 \\ 1 & 1 & 0 & 0 \\ 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 \end{pmatrix} \begin{pmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos(2A) & \sin(2A) & 0 \\ 0 & -\sin(2A) & \cos(2A) & 0 \\ 0 & 0 & 0 & 1 \end{pmatrix} \begin{pmatrix} 1 & -N & 0 & 0 \\ -N & 1 & 0 & 0 \\ 0 & 0 & C & S \\ 0 & 0 & -S & C \end{pmatrix} \cdot M_{rot} \begin{pmatrix} 1 \\ \cos(2P) \\ \sin(2P) \\ 0 \end{pmatrix}$$

59

and simplifying yields:

$$I = (1 - \cos(2A) \cdot N - N + \cos(2A) \sin(2A) \cdot C \sin(2A) \cdot S) \cdot M_{rot} \begin{pmatrix} 1 \\ \cos(2P) \\ \sin(2P) \\ 0 \end{pmatrix}$$

60

where an isotropic matrix was used to represent the material system sample.

To calculate the frequency content of the measured Intensity, the general rotating frequency component matraces are sequentially substituted for Mrot in the Eq. 60. to yield:

$$DC = (1 - \cos(2 \cdot A) \cdot N - N + \cos(2 \cdot A) \sin(2 \cdot A) \cdot C \sin(2 \cdot A) \cdot S) \cdot \begin{bmatrix} m11 & 0 & 0 & m14 \\ 0 & \frac{m22 + m33}{2} & \frac{m23 - m32}{2} & 0 \\ 0 & \frac{m32 - m23}{2} & \frac{m22 + m33}{2} & 0 \\ m41 & 0 & 0 & m44 \end{bmatrix} \begin{bmatrix} 1 \\ \cos(2 P) \\ \sin(2 P) \\ 0 \end{bmatrix}$$

$$A2 = (1 - \cos(2 \cdot A) \cdot N - N + \cos(2 \cdot A) \sin(2 \cdot A) \cdot C \sin(2 \cdot A) \cdot S) \cdot \begin{bmatrix} 0 & m12 & m13 & 0 \\ m21 & 0 & 0 & m24 \\ m31 & 0 & 0 & m34 \\ 0 & m42 & m43 & 0 \end{bmatrix} \begin{bmatrix} 1 \\ \cos(2 P) \\ \sin(2 P) \\ 0 \end{bmatrix} \quad 61$$

$$B2 = (1 - \cos(2 \cdot A) \cdot N - N + \cos(2 \cdot A) \sin(2 \cdot A) \cdot C \sin(2 \cdot A) \cdot S) \cdot \begin{bmatrix} 0 & -m13 & m12 & 0 \\ -m31 & 0 & 0 & -m34 \\ m21 & 0 & 0 & m24 \\ 0 & -m43 & m42 & 0 \end{bmatrix} \begin{bmatrix} 1 \\ \cos(2 P) \\ \sin(2 P) \\ 0 \end{bmatrix}$$

$$A4 = (1 - \cos(2 \cdot A) \cdot N - N + \cos(2 \cdot A) \sin(2 \cdot A) \cdot C \sin(2 \cdot A) \cdot S) \cdot \begin{bmatrix} 0 & 0 & 0 & 0 \\ 0 & \frac{m22 - m33}{2} & \frac{m32 + m23}{2} & 0 \\ 0 & \frac{m32 + m23}{2} & \frac{m33 - m22}{2} & 0 \\ 0 & 0 & 0 & 0 \end{bmatrix} \begin{bmatrix} 1 \\ \cos(2 P) \\ \sin(2 P) \\ 0 \end{bmatrix}$$

$$B4 = (1 - \cos(2 \cdot A) \cdot N - N + \cos(2 \cdot A) \sin(2 \cdot A) \cdot C \sin(2 \cdot A) \cdot S) \cdot \begin{bmatrix} 0 & 0 & 0 & 0 \\ 0 & \frac{-m32 - m23}{2} & \frac{m22 - m33}{2} & 0 \\ 0 & \frac{m22 - m33}{2} & \frac{m32 + m23}{2} & 0 \\ 0 & 0 & 0 & 0 \end{bmatrix} \begin{bmatrix} 1 \\ \cos(2 P) \\ \sin(2 P) \\ 0 \end{bmatrix}$$

where

$$N = \cos(2\Psi), C = \sin(2\Psi)\cos(\Delta), S = \sin(2\Psi)\sin(\Delta),$$

$$C2A = \cos(2A), S2A = \sin(2A), C2P = \cos(2P), S2P = \sin(2P):$$

Final Fourier Coefficients for a general rotating element ellipsometer system, where ' ϕ ' is the rotating azimuth of the rotating element:

$$\text{Beam_Intensity} = DC + A2 \cdot \cos(2\phi) + B2 \cdot \sin(2\phi) + A4 \cdot \cos(4\phi) + B4 \cdot \sin(4\phi)$$

$$DC = (-m11 \cdot C2A - C2P \cdot (m22 + m33) + S2P \cdot (m32 - m23)) \cdot \frac{N}{2} + (C2P \cdot S2A \cdot (m32 - m23) + S2P \cdot S2A \cdot (m22 + m33)) \cdot \frac{C}{2} \\ + S2A \cdot S \cdot m41 + m11 + \frac{1}{2} \cdot C2P \cdot C2A \cdot (m22 + m33) + \frac{1}{2} \cdot S2P \cdot C2A \cdot (m23 - m32)$$

$$A2 = (-m21 - C2A \cdot (m12 \cdot C2P + S2P \cdot m13)) \cdot N + (S2A \cdot (m42 \cdot C2P + S2P \cdot m43)) \cdot S + m21 \cdot C2A + S2A \cdot C \cdot m31 + C2P \cdot m12 + S2P \cdot m$$

$$B2 = (m31 + C2A \cdot (C2P \cdot m13 - S2P \cdot m12)) \cdot N + (-S2A \cdot (C2P \cdot m43 - m42 \cdot S2P)) \cdot S - m31 \cdot C2A + S2A \cdot C \cdot m21 - C2P \cdot m13 + S2P \cdot m$$

$$A4 = (C2P \cdot (m33 - m22) - S2P \cdot (m32 + m23)) \cdot \frac{N}{2} + (C2P \cdot S2A \cdot (m32 + m23) + S2P \cdot S2A \cdot (m33 - m22)) \cdot \frac{C}{2} \\ + \frac{1}{2} \cdot S2P \cdot C2A \cdot (m32 + m23) + \frac{1}{2} \cdot C2P \cdot C2A \cdot (m22 - m33) \quad 62$$

$$B4 = (C2P \cdot (m32 + m23) + S2P \cdot (m33 - m22)) \cdot \frac{N}{2} + (C2P \cdot S2A \cdot (m22 - m33) + S2P \cdot S2A \cdot (m32 + m23)) \cdot \frac{C}{2} \\ + \frac{1}{2} \cdot S2P \cdot C2A \cdot (m22 - m33) - \frac{1}{2} \cdot C2P \cdot C2A \cdot (m32 + m23)$$

If the general rotating element is an ideal compensator represented by the Mueller Matrix in Eq. 63, the Fourier Coefficients simplify to the expressions in Eq. 64.

$$M_{\text{ideal_compensator}} = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & 1 & 0 & 0 \\ 0 & 0 & \cos\delta & \sin\delta \\ 0 & 0 & -\sin\delta & \cos\delta \end{bmatrix} \quad 63$$

$$DC = (S2P \cdot S2A \cdot C + C2P \cdot (C2A - N)) \cdot \frac{(1 + \cos\delta)}{2} + 1 - \frac{1}{2} N \cdot C2A \quad A2 = -S2A \cdot S2P \cdot \sin\delta \cdot S \quad B2 = S2A \cdot C2P \cdot \sin\delta \cdot S \\ A4 = \frac{(1 - \cos\delta)}{2} \cdot (C2P \cdot (C2A - N) - S2A \cdot S2P \cdot C) \quad B4 = \frac{(1 - \cos\delta)}{2} \cdot (S2P \cdot (C2A - N) + S2A \cdot C2P \cdot C) \quad 64$$

In actual rotating compensator systems, finite bandwidth and imperfect collimation can induce an apparent depolarization into the Mueller Matrix of the compensator of the form shown in Eq. 65:

$$M_{\text{actual_compensator}} = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & 1-c & 0 & 0 \\ 0 & 0 & \cos\delta \cdot (1-b) & \sin\delta \cdot (1-b) \\ 0 & 0 & -\sin\delta \cdot (1-b) & \cos\delta \cdot (1-b) \end{bmatrix} \quad 65$$

and the Fourier Coefficients become:

$$\begin{aligned} DC &= (S2P \cdot S2A \cdot C + C2P \cdot (C2A - N)) \cdot \frac{(1 + \cos\delta \cdot (1-b) - c)}{2} + 1 - \frac{1}{2} \cdot N \cdot C2A & A2 &= S2A \cdot S2P \cdot \sin\delta \cdot S \cdot (1-b) \\ & & B2 &= S2A \cdot C2P \cdot \sin\delta \cdot S \cdot (1-b) \\ A4 &= \frac{(1 - \cos\delta \cdot (1-b) - c)}{2} \cdot (C2P \cdot (C2A - N) - S2A \cdot S2P \cdot C) & B4 &= \frac{(1 - \cos\delta \cdot (1-b) - c)}{2} \cdot (S2P \cdot (C2A - N) + S2A \cdot C2P \cdot C) \end{aligned}$$

66

If A.C. Normalization is used there is no sensitivity to these non-idealities, and the equations can be simply transformed as shown in Eqs. 67 to fit for an effective Compensator Retardance ' δ' ', and the effective non-idealities ' b' ' and ' c' ' will appear only in the D.C. term:

$$\begin{aligned} DC &= \left[(S2P \cdot S2A \cdot C + C2P \cdot (C2A - N)) \cdot \frac{(1 + \cos\delta - c)}{2} + 1 - \frac{1}{2} \cdot N \cdot C2A \right] \cdot (1+b) & A2 &= S2A \cdot S2P \cdot \sin\delta \cdot S \\ & & B2 &= S2A \cdot C2P \cdot \sin\delta \cdot S \\ A4 &= \frac{(1 - \cos\delta)}{2} \cdot (C2P \cdot (C2A - N) - S2A \cdot S2P \cdot C) & B4 &= \frac{(1 - \cos\delta)}{2} \cdot (S2P \cdot (C2A - N) + S2A \cdot C2P \cdot C) \end{aligned}$$

67

INVERSION OF FOURIER COEFFICIENTS TO EXTRACT ELLIPSOMETRIC COEFFICIENTS N, C AND S

The preceeding Equations can be inverted to extract N, C and S, given the Fourier Coefficients that are measured by an ellipsometer system:

$$N = \frac{((rDC \cdot C2P \cdot C2A + 1) a4 + C2A \cdot b4 \cdot S2P \cdot rDC - C2A \cdot cR)}{((rDC \cdot C2P + C2A) \cdot a4 + b4 \cdot rDC \cdot S2P - cR)}$$

$$C = \left(\frac{C2A^2 - 1}{S2A} \right) \cdot \frac{b4}{((rDC \cdot C2P + C2A) a4 + b4 rDC \cdot S2P - cR)}$$

68

$$S = \left(\frac{C2A^2 - 1}{S2A} \right) \cdot \frac{cR}{sR ((rDC \cdot C2P + C2A) \cdot a4 + b4 \cdot rDC \cdot S2P - cR)}$$

where

$$a2 = \frac{-A2 \cdot S2P + B2 \cdot C2P}{DC} \cdot (1 + b) \quad a4 = \frac{A4 \cdot C2P + B4 \cdot S2P}{DC} \cdot (1 + b) \quad b4 = \frac{-A4 \cdot S2P + B4 \cdot C2P}{DC} \cdot (1 + b)$$

$$rDC = \frac{(1 + \cos\delta - c)}{2} \quad cR = \frac{1 - \cos\delta}{2} \quad sR = \sin\delta$$

The traditional Ellipsometric Parameters are given by:

$$\Delta = \text{atan}\left(\frac{S}{C}\right) \quad \Psi = \text{atan}\left(\frac{\sqrt{C^2 + S^2}}{N}\right) \quad \% \text{Depolarization} = 100 \cdot (1 - N^2 - C^2 - S^2)$$

69

and if the Analyzer Azimuth 'A' is set to forty-five (45) degrees, and they can be calculated without even measuring the D.C. component of the signal, although the D.C. component remains necessary to enable calculating Depolarization, (as in Eq. 70).

$$\Delta = \text{atan}\left(\frac{cR}{sR} \frac{A2 \cdot S2P - B2 \cdot C2P}{A4 \cdot S2P - B4 \cdot C2P}\right) \quad \Psi = \text{atan}\left[\frac{\sqrt{(-A4 \cdot S2P + B4 \cdot C2P)^2 + \left(\frac{cR}{sR}\right)^2 \cdot (-A2 \cdot S2P + B2 \cdot C2P)^2}}{A4 \cdot C2P + B4 \cdot S2P}\right]$$

70

Where birefringent window(s) or lens(es) are present in the ellipsometric beam pathway and are characterized in terms of in-plane and out-of-plane retardance components, (as described in Allowed Patent Application Serial No. 09/162,217, said 217 Application being incorporated herein by reference), the true N, C and S Parameters can be extracted from measured Fourier Coefficients using Eqs. 71. Note that out-of-plane window

retardance effects on the data are analytically removed using these expressions:

$$N = \frac{((sR \cdot cr1 + sR \cdot rDC \cdot C2P \cdot C2A \cdot cr2) \cdot a4 - cR \cdot a2 \cdot sr1 + sR \cdot b4 \cdot rDC \cdot S2P \cdot cr2 \cdot C2A - sR \cdot cr2 \cdot C2A \cdot cR)}{((sR \cdot C2P \cdot rDC + sR \cdot cr1 \cdot cr2 \cdot C2A) \cdot a4 - sR \cdot cR + S2P \cdot b4 \cdot sR \cdot rDC - cR \cdot sr1 \cdot a2 \cdot C2A \cdot cr2)}$$

$$C = \frac{\left[\begin{aligned} &(-sr2 \cdot cR \cdot C2A \cdot (cr2 \cdot C2A + rDC \cdot C2P \cdot cr1)) \cdot a2 \dots \\ &+ sR \cdot (C2A \cdot cr2 \cdot cr1 \cdot S2A + rDC \cdot C2P \cdot S2A + rDC \cdot S2P \cdot sr2 \cdot C2A \cdot sr1) \cdot b4 - sR \cdot cR \cdot sr2 \cdot C2A \cdot sr1 \end{aligned} \right] \cdot N \dots}{\begin{aligned} &+ (cR \cdot sr2 \cdot C2A^2 \cdot rDC \cdot C2P \cdot cr1 \cdot cr2 + cR \cdot sr2 \cdot C2A) \cdot a2 + (-sR \cdot rDC \cdot C2P \cdot S2A \cdot C2A \cdot cr2 - sR \cdot cr1 \cdot S2A - sR \cdot rDC \cdot S2P \cdot sr2 \cdot C2A^2 \cdot sr1 \cdot cr2) \cdot b4 \\ &+ cR \cdot sr2 \cdot C2A^2 \cdot sR \cdot sr1 \cdot cr2 \end{aligned}}$$

$$\frac{((C2A \cdot cr2 + rDC \cdot C2P \cdot cr1) \cdot a2 + sR \cdot sr1) \cdot N + ((C2P \cdot sr1 \cdot C2A \cdot sr2 - S2P \cdot S2A) \cdot a2 \cdot rDC - sR \cdot sr2 \cdot cr1 \cdot C2A) \cdot C \dots}{(C2P \cdot sr1 \cdot S2A + sr2 \cdot C2A \cdot S2P) \cdot a2 \cdot rDC - sR \cdot cr1 \cdot S2A}$$

71

where:

cr1=cos(r1), sr1=sin(r1), cr2=cos(r2), sr2=sin(r2),
r1=out-of-plane entrance window retardance, r2=out-of-plane exit window retardance

It is noted that parameterization in calibration procedures can include DELTA offset due to birefringent effects of windows and/or lenses through which a beam of electromagnetic radiation passes, as well as wavelength offsets, (eg. wherein a calculated curve is shifted along a wavelength axis while retaining its general shape by any means).

GLOBAL REGRESSION MODE (GRM) 4.

In this (GRM) 4 Mode Material System, (Sample), PSI and DELTA are Parameterized as function of Reference Sample Surface Layer Thickness and Angle Of Incidence using well known optical model and optical constants for the substrate and film, and Compensator and Analyzer Characterizing Parameters are fit at

each Wavelength. This serves to pick-up subtleties in Retardance, Fast Axis Position and Rotation.

(GRM) 4 provides:

$$PFD_{p,n} \left(P, \psi(\tau, \theta), \Delta(\tau, \theta), g A_s, (C_s)_{p,n}, (P_s)_{p,n}, \delta_{p,n} \right) \quad 72$$

provides that Reference Material System, (Sample), PSI and DELTA parameters can be parameterized as functions of:

Reference Material System, (Sample), and or Surface Layer thereupon Thickness;

Angle of Incidence of the Electromagnetic Beam to a Reference Material System (Sample) surface;

in addition to what is shown infra in the previously reported (GRM) 3 which is described by Eq. 49.

It is also disclosed that the disclosed invention allows calculating Reflectance by using un-normalized A.C. and/or D.C. signals. As mentioned, the Kleim et al. Article cited in the Background Section, provides:

$$I = I_0 \cdot (DC + a2 \cdot \cos(2\omega t) + b2 \cdot \sin(2\omega t) + a4 \cdot \cos(4\omega t) + b4 \cdot \sin(4\omega t))$$

$$I_0 = K \cdot R_s \quad R_s = \frac{\overline{r_p \cdot r_p} + \overline{r_s \cdot r_s}}{2}$$

$$M_s = R_s \begin{pmatrix} 1 & -N & 0 & 0 \\ -N & 1 & 0 & 0 \\ 0 & 0 & C & S \\ 0 & 0 & -S & C \end{pmatrix}$$

$$DC = \frac{1}{2} \cdot (1 + \cos \delta) \cdot (\cos 2A \cdot \cos 2P - \cos 2P \cdot N + \sin 2A \cdot \sin 2P \cdot C) - \cos 2A \cdot N + 1$$

$$a2 = -\sin 2A \cdot \sin 2P \cdot \sin \delta \cdot S \quad b2 = \sin 2A \cdot \cos 2P \cdot \sin \delta \cdot S$$

$$a_4 = \frac{1}{2} \cdot (1 - \cos \delta) \cdot (\cos 2A \cdot \cos 2P - \cos 2P \cdot N - \sin 2A \cdot \sin 2P \cdot C)$$

$$b_4 = \frac{1}{2} \cdot (1 - \cos \delta) \cdot (\cos 2A \cdot \sin 2P - \sin 2P \cdot N + \sin 2A \cdot \cos 2P \cdot C)$$

5 where: " ω " is the rotational frequency of the rotating compensator element, " δ " is the retardance of the compensator, I_0 is the average intensity of the detected signal, M_s is the Mueller Matrix representation of an isotropic sample, and R_s is the average Reflectance of the sample. Note that for most
10 ellipsometric applications, R_s is lumped together with an arbitrary system throughput constant K , (K is a function of the light source intensity, detector sensitivity, and electronic gain). Both K and R_s cancel from the above expressions if the Fourier Coefficients (a_2 , b_2 , a_4 and/or b_4) are normalized,
15 either by dividing by the D.C. term, or dividing by the magnitude of the A.C. coefficients. However, if normalization is not performed, K and R_s information is present in the detected signal, in both the D.C. and A.C. (ie. Fourier Coefficients), signals.

20 While R_s information could be derived from the D.C. component of the signal, and D.C. offsets or drifts in the detector electronic would degrade the accuracy of the R_s data. Likewise, changes in ambient light collected by the detector
25 would also couple into the measured D.C. signal, and thereby corrupt the R_s determination.

30 However, using the A.C. signal is a more robust way to determine R_s , as locking into the modulated signal eliminates the problems previously described with utilizing the D.C. component. Assuming an analyzer azimuth of ± 45 degrees, the magnitude of the A.C. signal 2ω and 4ω components are:

$$I_0^2 \cdot (a^2 + b^2) = K^2 \cdot R_s^2 \cdot \sin^2 \delta \cdot S^2 \quad I_0^2 \cdot (a^4 + b^4) = K^2 \cdot R_s^2 \cdot \frac{1}{4} \cdot (C^2 + N^2) \cdot (\cos \delta - 1)^2$$

Since $N^2 + C^2 + S^2 = 1$ for a non-depolarizing sample, the following expressions can be written:

$$S^2 = \frac{I_0^2 \cdot (a^2 + b^2)}{K^2 \cdot R_s^2 \cdot \sin^2 \delta} \quad (C^2 + N^2) = \frac{4 \cdot I_0^2 \cdot (a^4 + b^4)}{K^2 \cdot R_s^2 \cdot (\cos \delta - 1)^2}$$

74

$$N^2 + C^2 + S^2 = 1 = \frac{I_0^2 \cdot (a^2 + b^2)}{K^2 \cdot R_s^2 \cdot \sin^2 \delta} + \frac{4 \cdot I_0^2 \cdot (a^4 + b^4)}{K^2 \cdot R_s^2 \cdot (\cos \delta - 1)^2}$$

$$K \cdot R_s = \sqrt{\frac{[(I_0 \cdot a^2)^2 + (I_0 \cdot b^2)^2]}{\sin^2 \delta} + \frac{4 \cdot [(I_0 \cdot a^4)^2 + (I_0 \cdot b^4)^2]}{(\cos \delta - 1)^2}}$$

Using the above expression, the $K \cdot R_s$ product can be determined using only the un-normalized A.C. components of the detected signal. To determine K , such that R_s can be calculated requires a calibration using a reference sample which has a known reflectance. The best way to do this would be to measure and fit an optical model to ellipsometric data acquired from a reference sample. The optical model derived from the ellipsometric data could then be used to calculate the average sample reflectance R_s , and then the system throughput constant K could be determined and fixed for subsequent measurements, allowing the unique determination of R_s using only A.C. signal components. Similar expressions can be either analytically derived or numerically evaluated to determine R_s from the A.C. components when the analyzer is not exactly ± 45 degrees, or if the compensator non-idealities require more complicated expressions for the Fourier coefficients. Stated generally, Sample Reflectance is

determined from the detector output signal without application of normalization to any D.C. and/or A.C. components thereof.

5 It is noted that use of Reflectance as determined from un-normalized data, preferably un-normalized A.C. data, but not excluding using un-normalized D.C. and/or A.C. data, can be useful in system calibration, particularly where sample defining parameters are simultaneously determined.

10 Finally, as it is of primary importance to the disclosed invention, it is to be specifically understood that the practice of ellipsometry involves characterizing electromagnetic beams as being comprised of two orthogonal components, each of which has a magnitude, which orthogonal components are separated by a
15 phase angle. Compensators enter retardation between the orthogonal components and thereby increase the phase angle therebetween. A rotating Compensator causes varying retardation between the orthogonal components over time.

20 The invention will be better understood by reference to the Detailed Description Section of this Disclosure, in conjunction with the accompanying Drawings.

SUMMARY OF THE INVENTION

5 It is therefore a primary purpose and/or objective of the invention to teach a spectroscopic ellipsometer for evaluating a sample comprising:

a broadband light source generating a beam having wavelengths extending over a range of at least 200 to 800 nm;

10 a polarizer disposed in the path of the light beam;

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20 a compensator disposed in the path of the light beam, said compensator for inducing phase retardations in the polarization state of the light beam, said compensator having characteristics other than substantially non-achromatic so that the amount of phase retardation varies with wavelength, over a range of wavelengths, less than is the case were a substantially non-achromatic compensator utilized, said compensator being rotated at an angular frequency of ω ;

an analyzer that interacts with the light beam after the beam interacts with the sample and with the compensator;

25 a detector that measure the intensity of the light beam after the interaction with the analyzer at a plurality of wavelengths across the wavelength range of at least 200 to 800 nm;

30 said detector generating a time varying intensity output signal simultaneously comprising 2ω and 4ω components; and

optionally a processor for evaluating the sample based on the

intensity output signal without, after the detector determines Intensity, the requirement that a 2ω component and a 4ω component be provided other than as used simultaneously in sample characterization.

5 It is another primary purpose and/or objective of the invention to teach a spectroscopic ellipsometer system which comprises a broadband electromagnetic radiation source means generating a beam having a wavelength extending between over a range of at least 200 to 800 nm; polarizer means disposed in the path of said beam; compensator(s) means disposed in the path of the beam, said compensator(s) means having characteristics selected from the group consisting of:

being substantially achromatic;
being pseudo-achromatic;
being other than substantially-non-achromatic;

so that the amount of phase retardation varies with wavelength less than is the case were a substantially non-achromatic compensator utilized, said compensator(s) means being rotated at an angular frequency of ω ;

analyzer means that interact with the beam after the beam interacts with the sample and the compensator(s) means; detector means that measure the intensity of the beam after the interaction with the analyzer means at a plurality of wavelengths across the wavelength range of at least 200 to 800 nm; said detector means generating a time varying intensity output signal comprising 2ω and 4ω component signals, said 2ω and 4ω signal components being simultaneously present at all wavelengths measured unless the 2ω signal is forced to 0.0 by a sample presenting with an ellipsometric DELTA of 0.0 as opposed to being caused to be 0.0 by said compensator(s) means; and optionally

further processor means for evaluating the sample based simultaneously on both the 2ω and 4ω intensity signal components at measured wavelengths.

5 It is yet another primary purpose and/or objective of the invention to teach a spectroscopic ellipsometer system comprising broadband electromagnetic radiation source means generating a beam having a wavelength extending between over a range of at least 200 to 800 nm; polarizer means disposed in the path of
10 said beam; compensator(s) means disposed in the path of the beam, said compensator(s) means being:

pseudo-achromatic;

15 in that the amount of phase retardation varies more with wavelength than is the case if a substantially achromatic compensator is utilized but in that the amount of phase retardation varies less than is the case if a substantially non-achromatic compensator is utilized, said compensator
20 mean(s) means being rotated at an angular frequency of ω ; analyzer means that interacts with the beam after the beam interacts with the sample and the compensator(s) means; detector means that measure the intensity of the beam after the interaction with the analyzer at a plurality of wavelengths
25 across the wavelength range of at least 200 to 800 nm; said detector means generating a time varying intensity signal comprising 2ω and 4ω component signals, said 2ω and
30 4ω signals being simultaneously present at all wavelengths measured unless the 2ω signal is forced to 0.0 by a sample presenting with an ellipsometric DELTA of 0.0 as opposed to being caused to be 0.0 by said compensator(s) means; and optionally further comprising processor means for evaluating the sample based simultaneously on both the 2ω and 4ω intensity signal components at measured wavelengths.

It is another objective and/or purpose of the invention to teach use of compensators in Spectroscopic Ellipsometers including Rotating Compensators which provide retardations in a range, (ie. max - min) of less than 90 degrees within a range of retardations bounded by at least 30 to less than 135 degrees, (thereby excluding 180 degrees), over a range of wavelengths.

It is another objective and/or purpose yet of the invention to teach a Spectroscopic Rotating Compensator Material System Investigation System, including at least one Photo Array comprised of a multiplicity of Diode Elements, for simultaneously detecting a Multiplicity of Wavelengths, which Spectroscopic Rotating Compensator Material System Investigation System can utilize both Achromatic and non-Achromatic Compensators of Berek-type with Optical Axis perpendicular to a surface thereof, and/or with Compensators with Optical Axis parallel to a surface thereof; and which Spectroscopic Rotating Compensator Material System Investigation System can be realized utilizing off-the-shelf Compensator and Spectrometer System components.

It is a further objective and/or purpose of the invention to teach that a preferred Compensator Design is comprised of a combination of a first and a second actual or effective zero-order wave plate, said first actual or effective zero-order wave plate being either a single zero-order waveplate or being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second actual or effective zero-order wave plate being either a single zero-order waveplate or comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes of the multiple order waveplate(s) in said second actual or effective zero-order wave plate being oriented at other than zero or ninety degrees,

nominally forty-five degrees, to the fast axes, respectively, of the multiple order waveplate(s) in said first actual or effective zero-order waveplate.

5 It is another objective and/or purpose of the invention to teach, in the context of a Spectroscopic Rotating Compensator Material System Investigation System, Evaluation of Calibration Parameters in a Mathematical Model thereof by a Mathematical Regression based technique involving utilization of at least one, at least-one-dimensional data set, obtained with the Spectroscopic Rotating Compensator Material System Investigation System oriented in a "Material System, (Sample), present" or in a "Straight-through" configuration.

10 It is yet another objective and/or purpose of the invention to teach, in the context of a Spectroscopic Rotating Compensator Material System Investigation System, Evaluation of Calibration Parameters in a Mathematical Model thereof by a Mathematical Regression based technique involving utilization of at least one multi-dimensional, data set(s) being obtained utilizing a selection from the group consisting of:

15 all of said at least one multi-dimensional data set(s), being obtained utilizing a single material system (MS) placed on said stage (STG) for supporting a material system (MS);

20 at least one of said at least one multi-dimensional data set(s), being obtained utilizing one material system (MS) placed on said stage (STG) for supporting a material system (MS), with another of said at least one multi-dimensional data set(s), being obtained utilizing another material system (MS) placed on said stage (STG) for supporting a material system (MS); and

at least one of said at least one multi-dimensional data set(s) being obtained with the spectroscopic rotating compensator material system investigation system oriented in a "straight-through" configuration wherein a polychromatic beam of electromagnetic radiation (PPCLB) produced by said source (LS) of a polychromatic beam of electromagnetic radiation, is caused to pass through said polarizer (P), pass through said analyzer (A), and interact with said dispersive optics (DO) such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements (DE's) in said at least one detector system (DET), with said polychromatic beam of electromagnetic radiation (PPCLB) also being caused to pass through at least one compensator(s) (C) (C') (C'') but without being caused to interact with any material system (MS) placed on said stage (STG) for supporting a material system (MS) other than open ambient atmosphere.

It is another objective and/or purpose of the invention yet to teach, in the context of a Spectroscopic Rotating Compensator Ellipsometer/Material System Investigation Systems, Evaluation of Calibration Parameters in a Mathematical Model thereof by a Mathematical Regression based technique involving utilization of said at least two, at least one-dimensional, data set(s) being obtained utilizing a selection from the group consisting of:

all of said at least two, at least one-dimensional data set(s), being obtained utilizing a single material system (MS) placed on said stage (STG) for supporting a material system (MS);

at least one of said at least two, at least one-dimensional data set(s) being obtained utilizing one material system (MS)

placed on said stage (STG) for supporting a material system (MS), and at least one of said at least two at least one-dimensional data set(s) being obtained utilizing one material system (MS) placed on said stage (STG) for supporting a material system (MS); and

at least one of said at least two, at least one-dimensional data set(s) being obtained utilizing one material system (MS) placed on said stage (STG) for supporting a material system (MS), and at least one of said at least two, at least one-dimensional data set(s) being obtained with the spectroscopic rotating compensator material system investigation system oriented in a "straight-through" configuration wherein a polychromatic beam of electromagnetic radiation (PPCLB) produced by said source (LS) of a polychromatic beam of electromagnetic radiation, is caused to pass through said polarizer (P), pass through said analyzer (A), and interact with said dispersive optics (DO) such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements (DE's) in said at least one detector system (DET), with said polychromatic beam of electromagnetic radiation (PPCLB) also being caused to pass through at least one compensator(s) (C) (C') (C'') but without being caused to interact with any material system (MS) placed on said stage (STG) for supporting a material system (MS) other than open ambient atmosphere.

It is another objective and/or purpose of the invention to teach that, where beneficial and desirable, Parameterization of Calibration Parameters, (such as Azimuthal Orientation Angle of Polarizer, Compensator(s) and Analyzer, and Material System, (Sample), PSI and DELTA, and Compensator Representing Matrix Components), as a function of a Data Set variable, (such as

Wavelength, or Polarizer and/or Analyzer Azimuthal Angle Rotation, or Angle-of-Incidence of an electromagnetic beam with respect to a surface of a Material System, (Sample), being investigated, or Thickness of a Material System, (Sample), or Surface Layer thereupon, or a DELTA Offset resulting from passage of the electromagnetic beam through a Birefringent Window or Lens, or a Wavelength Shift from a calculated ideal etc.), to reduce the number of Calibration Parameters which need be evaluated during a mathematical regression based Calibration Procedure, should be practiced.

It is yet another objective and/or purpose of the invention, to teach, in the context of a Spectroscopic Rotating Compensator Material System Investigation System, Evaluation of Calibration Parameters in a Mathematical Model thereof by a Mathematical Regression based technique involving utilization of data set(s) which are normalized utilizing a selection from the group consisting of:

a data set D.C. component;

a data set A.C. component;

a parameter derived from a combinations of a data set D.C. component and a data set A.C. component;

It is another purpose and/or objective of the invention to teach measurement of reflectance using un-normalized A.C. and/or D.C. components.

It is a general objective and/or purpose of the present Disclosure to provide experimentally determined documentation of the utility of the Spectroscopic Rotating Compensator Material

System Investigation System, in the form of results obtained from practice of the Mathematical Regression Calibration Method, and the Material System Investigation Data Acquisition Method.

5 It is another purpose and/or objective of the disclosed invention to disclose use of Compensators in which a Fast Axis Azimuthal Orientation varies with wavelength.

10 It is a general objective and/or purpose of the present Disclosure to provide experimentally determined documentation of the utility of the Spectroscopic Rotating Compensator Material System Investigation System, in the form of results obtained from practice of the Mathematical Regression Calibration Method, and the Material System Investigation Data Acquisition Method.

15 Other objectives and/or purposes will become obvious by a reading of the Specification.

BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 shows the basic components of Reflectance and Transmission Mode Material System Investigation Systems which can be operated in Spectroscopic Rotating Compensator Material System Investigation System (eg. Ellipsometer System), Modes.

Fig. 2 shows a Spectrographic Diode Array Spectrometer System Detector.

Fig. 3 shows a Reflectance Mode combination of components shown in Figs. 1 and 2.

Fig. 4 shows a Reflectance Mode combination of components shown in Figs. 1 and 2 in which three Fig. 2 Spectrographic Diode Array Spectrometer Systems are present and provided input via light fibers.

Fig. 5 shows a Reflectance Mode combination of components shown in Figs. 1 and 2 in which Multiple Orders produced by a Dispersive Optics are intercepted by multiple Photo Arrays.

Fig. 6 demonstrates the Parameterization Approach to modeling Calibration Parameters which the disclosed invention utilizes in certain cases.

Fig. 7 demonstrates a "Straight-through" configuration of a Spectroscopic Rotating Compensator Material System Investigation System.

Fig. 8a shows lined diffraction grating dispersion optics geometry.

Fig. 8b shows a blazed angle lined diffraction grating dispersion optics geometry.

Fig. 8c shows a holographic lined diffraction grating dispersion optics geometry.

Fig. 8d shows a prism dispersion optics geometry.

Fig 9a shows a Fiber Optic which is essentially circular at the left side and which becomes of a "slit" shape at the right side.

Fig. 9b shows a Fiber Optic which is essentially circular shaped along the entire length thereof, and which provides input to a "Slit" per se.

Fig. 9c shows a Trifrucated Fiber Optic which is essentially circular at the left side, which trifrucates and then is exemplified as becoming circular or of a "slit" shape at the right side.

Fig. 9d shows a Berek-type Compensator with an Optical Axis perpendicular to a surface thereof.

Fig. 9e shows a Compensator with an Optical Axis parallel to a surface thereof.

Fig. 9f demonstrates construction of a Zero-Order Quartz Waveplate from two Multiple Order waveplates.

Figs. 9g, 9h and 9i demonstrates construction of a preferred compensator system constructed from first and second effective Zero-Order Waveplates, each of which effective Zero-Order Waveplates is a constructed composite of two Multiple Order waveplates, the fast axes of which at least two composite effective Zero-Order Waveplates are oriented away from zero or

ninety degrees, and at a nominal forty-five degrees, with respect to one another. Optional additional third element(s) are indicated by dashed lines.

- 5 Fig. 9g2 shows three Zero Order Plates are contacted to one another instead of having space thereinbetween. Three element Compensators configured as suggested by Figs. 9g1, 9g2 and 9j can comprise a "Psuedo Achromatic" which can provide Retardation vs. Wavelength characteristics such as those presented in Fig. 10g2.

10 Fig. 9j demonstrates functional construction of another preferred compensator system constructed from first and second actual per se. Zero-Order Waveplates, each of which actual per se. Zero-Order Waveplate is an effective single plate, the fast axes of which at least two composite actual per se. Zero-Order Waveplates are oriented away from zero or ninety degrees, and at a nominal forty-five degrees, with respect to one another.

15 Fig. 9k shows a diagram demonstrating use of beam splitters to direct an incident electromagnetic beam into two detectors.

20 Fig. 9l shows a "polka-dot" beam splitter.

25 Fig. 10a shows a plot of a compensator retardation characteristic which depends as $(1/\text{wavelength})$, (dashed line), as well as a compensator characteristic, (solid line).

30 Fig. 10b shows calculated retardation vs. wavelength curves for two compensators which demonstrate $(1/\text{wavelength})$ retardation characteristics, (long and short dashed lines), and the retardation curve, (solid line), of an assembly as demonstrated in Fig. 9g1 which is arrived at by combining said two retarders with a 45 degree angle between the fast axes thereof.

Note that Figs. 9g1 and 9j show optional third elements present as dashed-lines. Addition of elements allows achieving a Compensator that provides better Psuedo-Achromatic charactreistics than does a single or dual element Compensator.

Fig. 10c shows a rescaled plot of the solid line curve shown in Fig. 10b.

Figs. 10d and 10e show results calculated for compensators as demonstrated in Fig. 9g1, wherein one waveplate is selected at 266 NM and the other at 633 NM., and wherein the fast axes are oriented at 45 degrees with respect to one another, over a wavelength range of from 190 to 730 NM.

Figs. 10f and 10g1 show that changing waveplate selection for a Fig. 9g1 compensator configuration, and the angle between fast axes thereof, provides alternative retardation plots over various wavelength ranges.

Fig. 10g2 shows retardation vs. wavelength for a three (3) Zero Order plate compensator. The retardation varies between about 47 degrees and 130 degrees over a wavelength range of 190 to 1700 nm. Said three (3) element compensator comprises a 422 nm quartz Zero Order waveplate sandwiched by two 633 nm quartz Zero Order waveplates. Figs. 9g1 and 9j, wherein the dashed lines represent a present third waveplate, demonstrate the physical realization.

Fig. 10h shows experimentally determined Compensator Retardance as a function of Wavelength. Note that, except for the presence of harmonic "wiggles", the curve closely corresponds to the calculated curve in Fig. 10c.

Fig. 10i shows experimentally determined Effective Input Polarizer Azimuthal Angle, (including the rotary effect of the

Compensator). Note the agreement with Fig. 10e.

Fig. 10j shows the experimentally determined effective Fast Axis of the Compensator Azimuthal Orientation. Note the agreement with Fig. 10d

Figs. 10k and 10L show experimentally determined Depolarization factors 'c' factor 'b' as defined in Eqs. 67.

Figs. 10m - 10o show PSI and DELTA Curves experimentally determined for Silicon Substrates with, respectively, 1 Micron, 250 Angstroms and 25 Angstroms of SiO_2 on the surface thereof. The experimentally determined data is essentially exact agreement with the generated data from a mathematical model fit.

DETAILED DESCRIPTION

INVENTION SYSTEM

5 Referring now to Fig. 1, there is demonstrated a Material
System Investigation System, (ie. a Spectroscopic Ellipsometer
System), with provision to investigate a Material System,
(Sample), (MS) in either a Reflection Mode (RM) or a Transmission
10 Mode (TM). It is to be noted that said Material System
investigation System is generally comprised of a Source of a
Polychromatic Beam of Electromagnetic Radiation (LS), (ie. a
Broadband electromagnetic radiation source), a Polarizer Means
(P), a Material System, (ie. Sample), supporting Stage (STG), an
15 Analyzer Means (A) and a Detector Elements (DE's) containing
Photo Array Detector Means System (DET). Also note, however,
that Fig. 1 shows Reflection Mode System Compensator(s) Means (C)
and (C') and Transmission Mode System Compensator(s) Means (C)
and (C'') as present. It is to be understood that a Compensator
20 Means can be placed ahead of, and/or after a Material System,
(Sample), (MS) supporting Stage (STG) in either a Reflection Mode
or Transmission Mode System. That is only Compensator Means (C)
or (C') or both Compensator Means (C) and (C') can be present in
a Reflection Mode System (RM), and only Compensator Means (C) or
(C'') or both Compensator Means (C) and (C'') can be
25 simultaneously present in the Transmission Mode System (TM).
Fig. 1 also shows the presence of a Processor (PS) for
performing calculations that evaluate a sample based on the
Detector (DET) intensity output signal, without separating
it into separate 2 and 4 component signals. Note that the
30 indicated processor (PS) is not programmed with the same type of
algorithm the processor in the Aspnes et al. Patents is
interpreted as containing. As the Patent 6,320,657 File Wrapper
shows, the Aspnes et al. detector provides the processor in the

Aspnes et al. invention a 2ω and a 4ω signal after determining an intensity. The present invention does not separately use the 2ω and 4ω signal components from a detector provided Intensity, but always operates simultaneously on both the 2ω and 4ω signals simultaneously, even if one, (ie. the 2ω signal), becomes 0.0, said 0.0 simply being valid data indicating the DELTA of the Sample is 0.0. It is noted that the Aspnes et al. 2ω signal being 0.0 provides no firm indication that the Sample DELTA is 0.0, as the Compensator therein can effect 180 degrees retardance at one of more wavelengths, which confuses the issue as to why the 2ω signal becomes 0.0. Recall that presently disclosed invention "Psuedo-Achromatic" compensators never provide a retardation of 135 degrees or greater, (hence never impose a 180 degree retardation at any wavelength over a range of wavelengths, emphasis added).

Now, the configuration in Fig. 1 could be operated as a Rotating Polarizer or Rotating Analyzer System. The disclosed Rotating Compensator Material System Investigation System, however, in the preferred operational mode, essentially fixes the Polarizer Means (P) and Analyzer Means (A) during Data Acquisition from a Material System (Sample) (MS) which is placed upon the Material System, (Sample), supporting Stage (STG), and causes at least one present Compensator Means ((C), and/or (C') or (C) and/or (C')), to Rotate during said Data Acquisition. This serves to effectively enter a continuously varying retardance between Orthogonal Components in a Polarization Beam of Electromagnetic Radiation exiting said Compensator Means which is caused to rotate. Where two (2) Compensator Means are present, one before (C) and one after ((C') or (C')) a Material System, (Sample), placed upon said Material System, (Sample) (MS) supporting Stage (STG), only one, or both said Compensator Means can be caused to Rotate in use. If both Compensator Means

are caused to rotate, both can be rotated at the same rotation speed, or different rotation speeds can be utilized. It is noted that the J.A. Woollam CO. Rotating Compensator Ellipsometer uses a "Stepper Motor" to cause Compensator rotation, and a common signal synchronizes both the Compensator and Detector. An alternative technique is to use a signal derived from the motor to synchronize the detector. It is further noted that fixing the Polarizer Means (P) and Analyzer Means (A) in use provides another benefit in that polarization state sensitivity to input and output optics during data acquisition is essentially non-existent. This allows use of Optic Fibers, Mirrors, Beam Splitters, Lenses etc. for input/output.

It is also mentioned that in the following it will be generally assumed that a Material System, (Sample), (MS) under investigation by a Spectroscopic Rotating Compensator Material System Investigation System is positioned upon the Material System, (Sample), Supporting Stage (STG). This need not be the case, as is described in Patent 5,706,087. For instance, a Material System (Sample), (MS) can be positioned in a Magneto-Optic System which is physically too large to be supported by said Material System, (Sample), Supporting Stage (STG). In such a case, an Electromagnetic Beam Directing Means (eg. a Mooney Rhomb or a Mirror etc), can be placed upon said Material System, (Sample), Supporting Stage (STG) and without realigning a Source of Polychromatic Electromagnetic Beam (LS) and said Detector Element (DE) containing Photo Array Detector System (DET), a Polychromatic Electromagnetic Beam provided by said Source of Polychromatic Electromagnetic Beam (LS) can be caused to interact with said remotely positioned Material System, (Sample), (MS), and with said Electromagnetic Beam Directing Means, thereby being directed into said Detector Element (DE) containing Photo array Detector System (DET).

Continuing, the disclosed invention utilizes a Broadband source of Polychromatic Electromagnetic Radiation (LS), and Fig. 2 shows that the Detector Elements (DE's) containing Photo Array Detector System (DET) is, in the preferred embodiment, comprised of a Photo Array which consists of a number of Diode Elements (DE's). In use a Dispersive Optics (DO) receives a Polychromatic Electromagnetic Beam (EPCLB) which has interacted with a Material System, (Sample), (MS) and passed through said Analyzer Means (A), and diffracts said Polychromatic Electromagnetic Beam (EPCLB), such that each Photo Array (PA) Diode Element (DE) intercepts an Essentially Single Wavelength, (eg. a small band of wavelengths centered about a central single wavelength). Note that a Focusing Element (FE) is shown in a dashed line format to indicate that its presence is optional. The Focusing Element (FE), when present, serves to provide a focused Polychromatic Beam of Electromagnetic Waves at the input to said Detector Elements (DE's) containing Photo Array Detector System (DET), and the Detector System (DET) provides 2ω and 4ω signals developed by the Diode Elements (DE's) in a sequential output or a parallel output from the Diode Elements (DE's). It is emphasized that a preferred Detector Elements (DE's) containing Photo Array Detector System (DET) is an "Off-the-Shelf-System" which includes a Focusing Element (FE), and provides a self contained Dispersive Optics (DO) and Diode Element (DE) Array. The "Off-The-Shelf-System" of said preferred embodiment of the Rotating Compensator Material System Investigation System is a Zeiss Diode Array Spectrometer System identified by manufacturer numbers in the group: (MMS1 (300-1150 nm); UV/VIS MMS (190-730 nm); UV MMS (190-400 nm); AND IR MMS (900-2400 nm)). Said identified Zeiss systems provide a very compact system comprising a multiplicity of Detector Elements (DE's), and provide focusing via a Focusing Element (FE), Slit (S), and single concave holographic grating dispersive optics (DO), as generally represented by Fig. 2. A Hamamatsu CCD Array Detector,

(Series S7030/S7031), with a quantum efficiency of 40% or more has been successfully utilized.

5 Note that Fig. 2 also shows the presence of a Beam Splitter (BS) and a Cross Hair containing Reticule (CH) in the Detector Elements (DE's) containing Photo Array Detector System (DET). If the Beam Splitter (BS), the Dispersive Optics (DO), the Focusing Element (FE), the Detector Elements (DE's) containing Photo Array (PA), and the Cross Hair containing Reticule (CH) are mounted so
10 as to move as a rigid unit, then it should be appreciated that causing an Alignment Electromagnetic Radiation Beam (ALB) which reflects to said Cross Hair containing Reticule (CH) to be present near a Cross Hair crossing point can effect good alignment of the Detector Elements (DE's) containing Photo Array Detector System (DET) with respect to an entering Polarized Beam of Electromagnetic Radiation (EPCLB). In practice such an arrangement has been found to work very well. It is further noted that the element identified as (CH) could represent a Quadrature Photodetector and Automatic Alignment Means, or other functionally suitable system.
20

It is also noted that a Compensator Means (C) (C'), (C'') can utilize an Off-the-Shelf Quarter-Wave-Plate with its Optical Axis in the plane of a surface thereof, (see Fig. 9e), and that a Pseudo-Zero-Order Waveplate can be constructed from two (2)
25 Multiple-Order Waveplates of different thicknesses (T1) and (T2) which have Optical Axes oriented Ninety (90) degrees to one another, such that the overall effect of retardation is in the Zero-Order, (see Fig. 9f). As discussed in more detail below, Figs. 9g1 -9j show that a particularly relevant Compensator Means involves a combination of two compensators means, each selected from the group consisting of: (actual or pseudo Quarter-Wave-Plates). Also, a Berek-type Compensator with its
30 Optical Axis perpendicular to a surface thereof, (see Fig. 9d),

can be is selected without special concern to its Achromatic Operating Characteristics, emphasis added. As well, said Compensator Means (C), (C'), (C'') can be made of essentially any functional material such as Quartz or Polymer etc.

5 Figs. 9g1, 9h and 9i demonstrate functional construction of a preferred compensator means system constructed from first (Z01) and second (Z02) effectively Zero-Order, (eg. Quartz or Bicrystalline Cadmium Sulfide or Bicrystalline Cadmium Selenide),
10 Waveplates, each of which effective Zero-Order Waveplates (Z01) & (Z02) is shown to be constructed from two Multiple Order waveplates, (ie. (MOA1) & (MOB1) and (MOA2) & (MOB2), respectively). The fast axes (FAA2) & (FAB2) of said second effective Zero-Order Waveplate (Z02) are oriented away from zero or ninety degrees, (eg. in a range around a nominal forty-five degrees such as between forty and fifty degrees), with respect to the fast axes (FAA1) & (FAB1) of said first effective Zero-Order Waveplate (Z01). In particular Fig. 9g1 is a cross-sectional side view of a preferred compensator (PC) constructed from a
15 first effective zero-order plate (Z01) which is constructed from two multiple order plates (MOA1) and (MOB1), and a second effective zero-order plate (Z02) which is constructed from two multiple order plates (MOA2) and (MOB2). An entered electromagnetic beam (EMBI) emerges as electromagnetic beam (EMBO) with a retardation entered between orthogonal components thereof with a Retardation vs. Wavelength such as demonstrated in
20 Figs. 15a - 15e. Figs. 9h and 9i are views looking into the left and right ends of the preferred Compensator Means (PC) as shown in Fig. 9g1, and show that the Fast Axes (FAA2) and (FAB2) of the second effective Zero-Order Waveplate (Z02) are rotated
25 away from zero or ninety degrees and are ideally oriented at forty-five degrees, with respect to the Fast Axes (FAA1) & (FAB1) of the first effective Zero-Order Waveplate (Z01). (Note that the fast axis (FAA1) of the first effective Zero-Order Waveplate
30

(ZO1) is shown as a dashed line in Fig. 9i, for reference). Fig. 9j demonstrates functional construction of another preferred compensator which is constructed from two per se. single plate Zero-Order Waveplates (MOA) and (MOB), which are typically made of materials such as mica or polymer. Note, It is to be understood that the space between retarder plates in Figs. 9g1 and 9j can be reduced from that shown, even to the point where said retarder plates make contact with one another. Hence the presence of the spatial separation of the retarder plates shown in Figs. 9g1 and 9j is not to be interpreted as indicating a required limitation. Fig. 9g2 shows three Zero Order Plates are contacted to one another instead of having space thereinbetween. Three element Compensators configured as suggested by Figs. 9g1, 9g2 and 9j can comprise a "Psuedo Achromatic" which can provide Retardation vs. Wavelength characteristics such as those presented in Fig. 10g2. (See discussion of Fig. 10g2 later in this Specification).

(It is specifically to be understood that a compensator means system can be comprised of at least one Zero-Order waveplate and at least one effectively Zero-Order waveplate in combination, as well as combinations comprised of two actual Zero-Order waveplates or two effectively Zero-Order waveplates. And, a compensator can comprise more than two Zero-Order waveplate and/or effectively Zero-Order waveplates. Figs. 9g1 and 9j, for instance, demonstrate in dashed lines the presence of additional Zero-Order waveplate and/or effectively Zero-Order waveplates. It is specifically noted that the dashed lines in Fig. 9g1 can represent a true single plate Zero-Order waveplate and the dashed lines in Fig. 9j an effectively Zero-Order waveplate. For instance, in Fig. 9j, the dashed lines can be an effective Zero-Order waveplate constructed from plates similar to (MOA1) and (MOB1). Also, the dashed lines in Fig. 9g1 can be interpreted represent a single Zero-Order waveplate similar to (MOA) in Fig. 9j, by assuming deletion of one dashed line. The

Claims are to be understood in light of this disclosure).

5 A preferred disclosed invention embodiment comprises at least one of said at least one compensator means (C) (C') (C''), which is selected from the group consisting of:

10 comprised of at least two per se. zero-order waveplates (MOA) and (MOB), said per se. zero-order waveplates (MOA) and (MOB) having their respective fast axes rotated to a position offset from zero or ninety degrees with respect to one another, with a nominal value being forty-five degrees;

15 comprised of a combination of at least a first (Z01) and a second (Z02) effective zero-order wave plate, said first (Z01) effective zero-order wave plate being comprised of two multiple order waveplates (MOA1) and (MOB1) which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second (Z02) effective zero-order wave plate being comprised of two multiple order waveplates (MOA2) and (MOB2) which are combined with the fast axes thereof oriented at a nominal
20 ninety degrees to one another; the fast axes (FAA2) and (FAB2) of the multiple order waveplates (MOA2) and (MOB2) in said second effective zero-order wave plate (Z02) being rotated to a position at a nominal forty-five degrees to the fast axes (FAA1) and (FAB1), respectively, of the multiple order waveplates (MOA1) and (MOB1) in said first effective zero-order waveplate (Z01);

25 comprised of a combination of at least a first (Z01) and a second (Z02) effective zero-order wave plate, said first (Z01) effective zero-order wave plate being comprised of two multiple order waveplates (MOA1) and (MOB1) which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, and said second (Z02)

effective zero-order wave plate being comprised of two multiple order waveplates (MOA2) and (MOB2) which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another; the fast axes (FAA2) and (FAB2) of the multiple order waveplates (MOA2) and (MOB2) in said second effective zero-order wave plate (ZO2) being rotated to a position away from zero or ninety degrees with respect to the fast axes (FAA1) and (FAB1), respectively, of the multiple order waveplates (MOA1) and (MOB1) in said first effective zero-order waveplate (ZO1);

comprised of at least one zero-order waveplate, ((MOA) or (MOB)), and at least one effective zero-order waveplate, ((ZO2) or (ZO1) respectively), said effective zero-order wave plate, ((ZO2) or (ZO1)), being comprised of two multiple order waveplates which are combined with the fast axes thereof oriented at a nominal ninety degrees to one another, the fast axes of the multiple order waveplates in said effective zero-order wave plate, ((ZO2) or (ZO1)), being rotated to a position away from zero or ninety degrees with respect to the fast axis of the zero-order waveplate, ((MOA) or (MOB));

Now, and very importantly, even though the Invention disclosed in this Specification is a Rotating Compensator Material System Investigation System which is Spectroscopic, (ie. simultaneously operates on a number of Wavelengths in a Beam containing many Electromagnetic Wavelengths, over a range of, for instance, 190 - 1700 nanometers), a Compensator Means (C), (C'), (C'') utilized therein can provide a Retardance which varies with Wavelength and still be usable. A Compensator Means (C), (C'), (C'') does however, typically, have to be of a nature to allow passage of a Polychromatic Electromagnetic Beam therethrough without causing significant Attenuation, Deviation or

Displacement in the Direction of Propagation thereof. Particularly as regards Deviation and Displacement, if this is not the case, difficult to compensate complexities are caused in Detector Elements (DE's) containing Photo Array Detector System (DET) Detector Element Output Signals.

The reason a Spectroscopic Ellipsometer can operate with a Compensator Means (C), (C'), (C'') that does not provide even close to a Constant Ninety (90) Degree Retardance over a range of Wavelengths, (which would constitute Ideal Characteristics), is that a Regression based Calibration Procedure utilized, (see the Disclosure of the Invention Section of this Specification), provides Wavelength dependent Compensation effecting values for Calibration Parameters as required in a developed Mathematical Model of the Rotating Compensator Material System Investigation System, (ie./eg. Rotating Compensator Spectroscopic Ellipsometer). As better described in the Disclosure of the Invention Section of this Disclosure, the Inventors develop a Calibration Parameter Containing Mathematical Model of the Rotating Compensator Material System Investigation System by, for instance, utilizing Matrix Representations for various System Components involved, then multiplies out the Matrices in an appropriate order to provide a Transfer Function. This applies for all Wavelengths monitored by a Detector Elements (DE's) containing Photo Array Detector System (DET) Detector Element (DE). Next, Data Set(s) are Experimentally obtained as a function of wavelength and typically as a function of various settings of the Polarizer Means (P) or Analyzer Means (A), (or both could be rotated to various positions), while a Compensator Means (C) rotates at, typically though not necessarily, Twenty (20) to Thirty (30) Hz. Other rotation speeds can be utilized and if two Compensator Means (C) (C') are present one or both can be caused to rotate, and if both are caused to rotate, as mentioned infra herein, they can be caused to rotate at the same,

or different, speeds. (Note that Data Set(s) could also be achieved utilizing variation of Angle-Of-Incidence of a Beam of Polychromatic Radiation with respect to a Material System, (Sample), under investigation). Calibration Parameters in the Mathematical Model are then evaluated by, typically, Mean-Square-Error based Regression onto the Data Set(s). It is also possible to effectively find Calibration Parameter containing Mathematical Expressions for Coefficients of Mathematical Series, (eg. Fourier Series), which comprise the Mathematical Model Transfer Function, and calculate Numerical Values for the Coefficients from the Data Set(s), then effectively perform Regression of said Calibration Parameter containing Mathematical Expressions for Coefficients of Mathematical Series Transfer Function onto said Numerical Values for the Coefficients from the Data Set(s). It is emphasized that a single Two-Dimensional Data Set has been found sufficient to allow excellent Calibration results to be achieved. Said Two-Dimensional Data Set typically is Intensity vs. Wavelength, and Polarizer Means or Analyzer Means Azimuthal Rotation Angle settings. In addition, said Two-Dimensional Data Set can be obtained from a Rotating Compensator Material System Investigation System oriented so that a Polychromatic Beam of Electromagnetic Radiation interacts with a Material System, (Sample), (ie. the "Sample Present" Mode---see Figs. 1, 3, 4, and 5)), or such that said Polychromatic Beam of Electromagnetic Radiation passes through the Rotating Compensator Material System Investigation System without interacting with a Material System, (Sample), other than a Material System, (Sample), comprised of "Open Atmosphere", (ie. the "Straight-Through" Mode--see Fig. 7).

The Rotating Compensator Material System Investigation System can also, of course, be Calibrated utilizing more than one Data Set and such a procedure is reported in Patent No.

5,706,212, wherein a Rotating Compensator Material System Investigation System utilized in the Infra-red band of wavelengths, requires that two (2) Data Sets be present, (eg. selected with the Rotating Compensator Material System Investigation System oriented in a manner selected from the group: ("Straight-Through", "Material System, (Sample), Present", "Alternative Material System, (Sample), Present")). Both Data Sets are simultaneously utilized in a Regression Procedure to evaluate numerous Calibration Coefficients in a Mathematical Model which is described in the 212 Patent. The reason that only one (1) Data Set is can suffice to practice the described Calibration Procedure, is that the number of Calibration Parameters required by the Mathematical Model of the system, (which is not operated in the Infra-red range of wavelengths), is much fewer than the number of Calibration Parameters required by the Mathematical Model of the Rotating Compensator Material System Investigation System operated in the Infra-red range of wavelengths. The Rotating Compensator Material System Investigation System Mathematical Model typically involves as few as Five (5) Calibration Parameters, (where only one Compensator Means is present), in combination with simultaneous determination of a Material System, (Sample), PSI and DELTA. (It is noted that a straight-through mode essentially provides open atmosphere as a Material System, (Sample), and that the PSI and DELTA of open atmosphere are forty-five (45) degrees and zero (0.0) degrees, respectively). Said Five (5) Calibration Parameters are Azimuthal Orientation Angles for Polarizer Means (Ps), Analyzer Means (As), Compensator Means (Cs), and Compensator Retardance Parameters (P0) and (P1). Equations (45) and (46) serve as further demonstration of this point. (Note that the (Ps), (Cs) and (As) Azimuthal Orientation Calibration Angles can be thought of as serving to align the Polarizer Means, Compensator Means and Analyzer Means Azimuths with a Material System, (Sample), Frame of Reference). Of

course, if two Compensator Means are present then an additional Compensator Orientation Angle (Cs2) and Compensator Retardance Parameters (P0') and (P1') would also have to be evaluated. (It is noted that Retardation entered between orthogonal components of a Polarized Electromagnetic Beam, by a Compensator Means, is accounted for by a Matrix Component, and typically the r4 term of a Jones Matrix, but such is accounted for by Compensator Retardation Parameters (P0), (P1), (P0'), (P1') in the presently described Calibration Procedure).

A more complex calibration procedure provides for obtaining two (2) or three (3) data sets, and simultaneously regressing thereonto. A more complex calibration procedure can be beneficial where, for instance, a large wavelength range is being utilized and/or where multiple Angles of Incidence are to be utilized, and/or where it is desired to determine component "De-Polarization" effects and/or evaluate Mueller Matrix components. Where a multiple data set calibration procedure is practiced, a first data set is typically obtained utilizing a silicon substrate sample with two-hundred (200) to three-hundred (300) Angstroms, (eg. a nominal two-hundred-fifty (250) Angstroms), of silicon-dioxide on the surface thereof. A second data set can be obtained utilizing a sample which provides a large Ellipsometric PSI value, and an Ellipsometric DELTA value of between thirty (30) and one-hundred-fifty (150) degrees. Internal reflections from the hypotenuse of a right angle prism, either uncoated or coated with aluminum, or an optically thick metallic film, will provide such characteristics. Figs. 1, 3, 4 and 5 demonstrate sample present data set gathering configurations of a Rotating Compensator Ellipsometer System. A third data set can be obtained with the ellipsometer system configured in a "straight-through" configuration, (see Fig. 7), wherein the effective sample PSI is forty-five (45) degrees and

the effective sample DELTA is zero (0.0) degrees.

In general, the disclosed invention provides that at least one, at least one-dimensional, data set(s) be obtained utilizing a selection from the group consisting of:

all of said at least one, at least one-dimensional data set(s), are obtained utilizing a single material system (MS) placed on said stage (STG) for supporting a material system (MS), with which material system, (sample) (MS) the beam of electromagnetic radiation (PPCLB) is caused to interact;

at least one of said at least one, one-dimensional data set(s) is obtained utilizing one material system (sample) (MS) placed on said stage (STG) for supporting a material system, (sample) (MS), and at least one other of said at least one at least one-dimensional data set(s) is obtained utilizing another material system, (sample) (MS) placed on said stage (STG) for supporting a material system, (sample) (MS)), with which material system(s), (samples), (MS) the beam of electromagnetic radiation (PPCLB) is caused to interact; and

at least one of said at least one-dimensional data set(s) is obtained with the spectroscopic rotating compensator material system investigation system oriented in a "straight-through" configuration wherein a polychromatic beam of electromagnetic radiation (PPCLB) produced by said source (LS) of a polychromatic beam of electromagnetic radiation, is caused to pass through said polarizer means (P), pass through said analyzer means (A), and interact with said dispersive optics (DO) such that a multiplicity of essentially single wavelengths are caused to simultaneously enter a corresponding multiplicity of detector elements (DE's) in

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said at least one detector system (DET), with said polychromatic beam of electromagnetic radiation (PPCLB) also being caused to pass through at least one compensator means (C) (C') (C'') but without being caused to interact with any material system, (sample), (MS) placed on said stage (STG) for supporting a material system, (sample), (MS).

(Note: Preferred practice is to obtain at least two, at least one dimensional data sets; or at least one multiple dimension data set upon which to regress).

Continuing, where a multiple data set calibration procedure is utilized to calibrate a rotating compensator material system investigating system for measuring Ellipsometric and Depolarization/Mueller Matrix values, it is also disclosed that it has been found desirable to normalize data to D.C. in some portions of the calibration, and to an A.C. derived term in other portions thereof. Equations such as those presented in EQS. 35b and 35c, (which are derived from Fourier Coefficients), serve as examples of A.C. data normalization parameters.

Preferred calibration procedure practice provides that data be normalized to A.C. where determining compensator means retardation (R), polarizer means azimuth (P) and compensator means fast axis azimuth (C) are fit, and that data be normalized to D.C. where optical element Depolarization/Mueller Matrix values are fit. (For additional insight, see discussion in the Disclosure Of The Invention Section of this Specification regarding EQNS. 63 - 69, which define parameters 'b' and 'c').

Now, it is to be understood that the system of the Spectroscopic Rotating Compensator Material System Investigation System is basically found in a combination of components shown in

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Figs. 1 and 2, the basic result of said combination, for a Reflection Mode System, being shown in Fig. 3. That is, Fig. 3 shows a Spectroscopic Reflection Mode version of the Rotating Compensator Material System Investigation System shown in Fig. 1, with the Fig. 2 Detector Elements (DE's) containing Photo Array Detector System (DET) shown present directly after the Analyzer (A).

Fig. 4 shows a Reflection Mode System configuration in which three (3) Detectors (Det 1), (Det 2) and (Det 3) are fed input by Fiber Optics (LF1), (LF2) and (LF3) present in a Fiber Optic Bundle exiting Fiber Optic Connector (LFC). Said Fiber Optic Connector (LFC) receives a Polarized Electromagnetic Beam (EPCLB) exiting the Analyzer (A). (Note that a Fig. 9c at least Bifrucated Fiber Optic could be utilized). Said three (3) Detectors (Det 1), (Det 2) and (Det 3) can be previously disclosed Off-the-shelf Zeiss Diode Array Spectrometers, and can each comprise a Focusing Element (FE) in functional combination with a Dispersive Optics (DO) and a Diode Element (DE) containing Photo Array (PA).

Fig. 5 shows that the described system can cause a Polychromatic Beam of Polarized Electromagnetic Radiation (PPCLB) to, after interaction with a Material System, (Sample), (MS), reflect therefrom. Fig. 5 shows that the Reflected Polarized Beam of Electromagnetic Radiation (EPCLB), is caused to impinge upon a Dispersive Optics (DO), (eg. a Diffraction Grating), such that a plurality of Orders (+ORD2, +ORD1, -ORD1 and -ORD2) are produced. Each said Order is comprised of a spectrum of Wavelengths, and Fig. 5 shows that Wavelengths in said Orders (+ORD2, +ORD1, -ORD1 and -ORD2) can be intercepted by Detector elements (DE's) in Photo Arrays (PA). Some embodiments of a Rotating Compensator Ellipsometer System utilize such a system. It is noted that the Dispersive Optics (DO) is typically

rotatable so that the direction each Order of wavelengths generally proceeds from said Dispersive Optics (DO) is adjustable. Note that Fig. 5 also shows the presence of Filters (F1). It is noted that Wavelengths for adjacent Orders overlap, and said Filters (F1) allow a user to pass only desired Wavelengths, as well as reduce background radiation entry to Photo Arrays (PA's). Typically a Focusing Element is not present in a Fig. 5 embodiment.

It is also noted that Fiber Optics can be utilized to carry Polychromatic Electromagnetic Radiation from a Source thereof (LS) to the position of a Polarizer Means (P), or from the position of an Analyzer Means (A) to a Detector (DET) in Figs. 1 - 5.

Analogically similar figures to those shown in Figs. 3 - 5, but oriented for use in a Transmission Mode are not shown, but should be understood as within the scope of the implied by Fig. 1.

Continuing, the described invention achieves a Spectroscopic Rotating Compensator Material System Investigation System (eg. Spectroscopic Rotating Compensator Ellipsometer System), preferably utilizing an "Off-The-Shelf" compact Spectrometer Systems, and utilizing "Off-The-Shelf" Compensator Means Components which are not at all "ideal", as regards Achromaticity. To put this into perspective, it is noted that prior to about 1997, there was no known Spectroscopic Rotating Compensator Ellipsometer available in the market-place. It is believed that this is because it has previously been believed that to achieve such a System an Achromatic Rotating Compensator (RC) would be required. Such Compensators are not generally commercially available, hence, are expensive and reasonable approximations thereof typically must be individually fabricated.

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(Note, as described in Patent No. 5,706,212, a Dual-Rhomb Rotating Compensator (RC) which provides about seven (7%) percent variation in Retardation effected over a range of Wavelengths of approximately 2 to 14 microns, has been developed at the University of Nebraska. However, it is not clear that the identified University of Nebraska Dual-Rhomb Rotating Compensator (RC) would operate "Substantially Achromatically" outside the identified range of wavelengths, but would rather, as is generally the case with all physically realizable Compensators, it would operate Psuedo-Achromatically over a larger wavelength range).

For general information, Figs. 8a through 8d show various Dispersive Optics geometries. Fig. 8a shows a lined geometry diffraction grating (DGDO). The grating lines (GL) are essentially rectangular in cross-section with a spacing (a) therebetween. Fig. 8b shows a "Blazed" geometry Diffraction Grating Dispersive Optics (BDGDO). The Blazing Angle (BA) shifts reflected diffracted energy between "Orders" such into +ORD1 and -ORD1 from a typically useless ORD0 which projects perpendicularly back from the surface of said Dispersive Optics shown in Fig. 5. Fig. 8c shows a cross-sectional view of a Holographic Diffraction Grating Dispersion Optics (HDGDO) as is present in the Off-the-Shelf (Zeiss Diode Array Spectrometer systems identified infra herein. Said Zeiss Systems utilize a Holographic configuration in a concave shaped system). Fig. 8d shows a Prism Dispersive Optics (P1), with a Polarized Polychromatic Electromagnetic Beam (PPCCLB) entering Side (S1), and exiting Side (S2) and Side (S3) as Diffracted Beams in two "Orders" (ORDQ1) and (ORDP1) respectively. Note that a coating (OC) causes partial internal reflection of beam (PPCCBA) into beam (PPCLBB) to produce two "Orders". Any functional Diffraction effecting element can be utilized as a Dispersive Optics (DO) in the decribed invention.

As the invention can utilize Fiber Optics, certain geometries thereof are shown in Figs. 9a through 9c. Fig. 9a shows a Fiber Optic which is essentially circular at the left side and which becomes of a "slit" shape at the right side. Fig. 9b shows a Fiber Optic which is essentially circular shaped along the entire length thereof, and which provides input to a "Slit" per se., (as is functionally utilized in the embodiment shown in Fig. 2). The effects achieved by the Fiber Optics in Figs. 9a and 9b are similar. Fig. 9c shows a Trifrucated Fiber Optic which is essentially circular at the left side, which trifrucates and then is exemplified as becoming circular or a of a "slit" shape at the right side. Use of an effectively Trifrucated Fiber Optics is shown applied in Fig. 4. (Noted that Optical Fibers are utilized only as convenient means by which to transport electromagnetic radiation and not to modify polarization state. Also, it has been found that a beam splitter can be used instead of the bifrucated fibers. Fig. 9k, for instance, shows a diagram demonstrating use of beam splitters to direct an incident electromagnetic beam into two detectors, and Fig. 9l shows a "polka-dot" beam splitter which has been found to work well, (ie. Edmond Scientific part number 46-457 comprising a plate which is effectively half coated with a multiplicity of reflective regions such that approximately half of an incident electromagnetic beam reflects from, and half passes through). Fig. 9k also shows use of a beam splitter to provide a 10% of incident electromagnetic beam as an alignment beam directed into a four quadrant detector, and demonstrates optional use of reflective means, (eg. a simple mirror or perhaps beam folding optics as described in Patent 5,969,818 to Johns et al.). The presence of focusing lenses (optional), is also demonstrated, as are the presense of, where functional, fiber optic means to guide electromagnetism to indicated detectors #1 and #2.

METHOD OF CALIBRATION DISCLOSED IN PATENT 5,872,630.

For insight, material presented in Parent Patent No. 5,872,603 is again presented directly.

(Note, the Calibration Method is better described in the Disclosure of the Invention Section of this Specification. The following is to be considered as supplemental to the description provided in said Disclosure of the Invention Section).

In use, the Spectroscopic Rotating Compensator Material System Investigation System is modeled mathematically, with Calibration Parameters being included in said Mathematical Model. Said Calibration Parameters are evaluated by a regression based approach based upon Data Set(s) obtained at a multiplicity of Angles-of-Incidence, and/or Wavelengths and/or Polarizer or Analyzer Rotation Angle Settings etc. (Note that a relatively easily obtained Two Dimensional Data Set as a function of Wavelength, and either Polarizer or Analyzer Azimuthal Angle Setting, is greatly preferred and has been found to be sufficient). As mentioned infra herein, typically, Matrix representations of the Polarizer Means (P), Compensator Means (C), Analyzer Means (A), are utilized, with calibration parameters appearing in Matrix Components. Once evaluation of the Spectroscopic Rotating Compensator Ellipsometer System (RC) Calibration Parameters is effected, a Material System, (Sample), (MS) can be subjected to investigation thereby, with otherwise unexplained changes effected in a Beam of Polarized Electromagnetic Radiation.(LB), present after interaction with a Material System, (Sample), (MS), being attributed to said Material System, (Sample), (MS). (It is also to be noted that PSI and DELTA associated with a Material System, (Sample), at a specific Angle-Of-Incidence can be simultaneously evaluated with Calibration Parameter values if a Data Set is obtained utilizing a Material System, (Sample), present mode and the Mathematical

Model includes said Material System, (Sample), PSI and DELTA as functions of, for instance, Material System, (Sample), Thickness and/or Material System Surface Layer Thickness, and Angle of Incidence of the Electromagnetic Beam with respect to the Material System, (Sample), Surface, as Fit Parameters).

Fig. 6 demonstrates a "Parameterization" approach to modeling Calibration Parameters in a Mathematical Model which was of more importance in the methodology of Patent 5,872,630. Said example is retained herein as it is easy to understand. In that light, it must be understood that Calibration Parameters are often a function of Wavelength. For instance, the Retardation provided by a Compensator often varies inversely with wavelength. Where this is the case typical Mathematical Regression based evaluation of Calibration Parameters requires that a value for a Calibration Parameter be determined at each wavelength monitored. However, Fig. 6 shows that a plot of a Calibration Parameter vs. Wavelength can yield a locus which can be accurately modeled by a Mathematical Equation which requires only a few constants be known to allow calculation of the Calibration Parameter at a given Wavelength. For instance, Fig. 6 shows that a value for a Wavelength $W(n)$ can be calculated knowing a Channel Number (n) , (ie. Diode Element in an Array, such as shown in Figs. 2 - 5), from which a signal is obtained, and values for three constants $C0$, $C1$ and $C2$. Knowing values for Parameters $CP0$ and $P1$ as well allows calculating a Calibration Parameter Value (CP) given a Diode Element Array Channel Number (n) . It can occur that (n) is two-hundred (200) or more and if a non-Parameterized approach to calibration is utilized, two-hundred (200) or more values for Calibration Parameter CP would have to be determined and stored. However, utilizing the Calibration Parameter Parameterization approach, it can be seen that a Regression procedure must return values for only Two (2) variables, ($CP0$ and $P1$). Also, if a Calibration Procedure were selected to include

Angle-Of-Incidence (AOI) as a Data Set variable, it is known that where a Calibration Procedure utilizes a "Material System, (Sample), Present" configuration for acquiring data, that the PSI and DELTA values for the Material System, (Sample), will vary with said (AOI), and Material System, (Sample) and/or Surface Layer thereupon Thickness. (Note, said PSI and DELTA are equivalent to Calibration Parameters in a Regression procedure which serves to evaluate Calibration Parameters based upon Data obtained with a Material System present approach). A similar Parameterization approach could be applied to provide equations for calculating a PSI and a DELTA value given an (AOI) and/or, Material System, (Sample), or Surface Layer thereupon Thickness, each of said equations involving only a few variables which would have to be evaluated by a Regression procedure. (Note, the concept of "Parameterization" is often encountered in the modeling of Dielectric Functions, wherein one or more Lorentz Oscillator(s) is/are utilized. Lorentz Oscillator Structures require only a Magnitude, Energy and a Broadening Calibration Parameter be evaluated to be fully defined. Some peak regions of a Dielectric Function can be adequately modeled by said three evaluated Calibration Parameters, however, the peak and tail regions of a Lorentz Oscillator Structure are not mathematically separate and while a Lorentz Oscillator Structure might adequately define a peak region in a Dielectric Function plot, it is often inadequate in non-peak regions. This problem is the focus in Patent No. 5,796,983 which teaches Finite Width Oscillator Structures comprised of Finite Order Polynomials and/or Finite Magnitude Essentially Zero Width Discontinuities as replacement for Lorentz Oscillator Structures). Where beneficial, Parameterization of Calibration Parameters can be utilized. That is, where a plot of a Calibration Parameter vs. a Data Set of Independent Variable demonstrates that Parameterization can be applied with benefit, the Parameterization of Calibration Parameter approach, with respect

to some Data Set Independent Variable, can be applied.

5 The Spectroscopic Rotating Compensator Material System Investigation System then is comprised of Components as identified in Figs. 1 - 5, and utility derives from the Calibration Method which utilizes Regression, including Parameterization of Calibration Parameter where desired and beneficial, to evaluate Calibration Parameters in a Mathematical Model of said Spectroscopic Rotating Compensator Material System Investigation System.

APPLICATION RESULTS

15 Results of application of Global Regression Modes (GRM1), (GRM2) and (GRM3) are shown in Patent 5,872,630.

20 The preferred approach involves practice of Global Regression Mode (GRM) 4, which, along with previously reported Global Regression Modes (GRM1), (GRM2) and (GRM3), is better described in the Disclosure Of The Invention Section of this Specification. (It is emphasized that presently preferred practice under Global Regression Mode (GRM) 4 involves parameterizing Material System, (System), PSI and DELTA values utilizing electromagnetic beam Angle Of Incidence and Material System, (Sample), and/or Surface Layer thereupon Thickness, as independent variables. See Eqn. 72 in the Disclosure of the Invention Section of this Specification for better mathematical insight).

30 Fig. 10a shows a plot of a compensator retardation characteristic which depends as $(1/\text{wavelength})$, (dashed line), as well as a compensator characteristic, (solid line). The important thing to note is that a selected range of wavelengths

over which a retardation of between seventy-five (75) and one-hundred-thirty (130) degrees is developed, is much greater for said compensator means. As disclosed in the Disclosure of the Invention Section of this Specification, a spectroscopic rotating compensator material system investigation system typically comprises at least one compensator means which produces a retardance of, preferably, between seventy-five (75) and one-hundred-thirty (130) degrees over a range of wavelengths defined by a selection from the group consisting of:

- a. between one-hundred-ninety (190) and seven-hundred-fifty (750) nanometers;
- b. between two-hundred-forty-five (245) and nine-hundred (900) nanometers;
- c. between three-hundred-eighty (380) and seventeen-hundred (1700) nanometers;
- d. within a range of wavelengths defined by a maximum wavelength (MAXW) and a minimum wavelength (MINW) wherein the ratio of $(MAXW)/(MINW)$ is at least one-and-eight-tenths (1.8).

Acceptable practice however, provides for the case wherein at least one of said at least one compensator(s) provides a retardation vs. wavelength characteristic retardation range of less than Ninety (90) degrees over a range of Thirty (30.0) and less than one-hundred-thirty-five (135) degrees, over a range of wavelengths specified from MINW to MAXW by a selection from the group consisting of:

- a. MINW less than/equal to one-hundred-ninety (190) and

MAXW greater than/equal to seventeen-hundred (1700)
nanometers;

b. MINW less than/equal to two-hundred-twenty (220) and
MAXW greater than/equal to one-thousand (1000)
nanometers;

c. within a range of wavelengths defined by a
maximum wavelength (MAXW) and a minimum wavelength
(MINW) range where $(MAXW)/(MINW)$ is at least four-and
one-half (4.5).

(NOTE, the specified vales and ranges can not be achieved by
single plates with $(1/\text{wavelength})$ retardation characteristics).

Fig. 10b shows calculated retardation vs. wavelength curves
for two compensators which demonstrate $(1/\text{wavelength})$ retardation
characterics, (long and short dashed lines), and the retardation
curve, (solid line), of an assembly configuration as
demonstrated in Fig. 9g1 which is arrived at by combining said
two retarders with a 45 degree angle between the fast axes
thereof.

Fig. 10c shows a re-scaled plot of the solid line curve
shown in Fig. 10b.

Figs. 10d and 10e show results calculated for a compensator
means as demonstrated in Fig. 9g1, wherein one waveplate is
selected at 266 NM and the other at 633 NM., and wherein the fast
axes are oriented at 45 degrees with respect to one another. The
wavelength range is from 190 to 730 NM,, (ie. deep UV to
Visable). Fig. 10d shows the calculated effective fast axis
orientation of a two plate compensator means and Fig. 10e
shows the calculated effective rotary power. Also, as discussed

in the Jones paper identified in the Background Section of this Specification, an arbitrary sequence of retarder elements can be mathematically represented by a single compensator means with "effective" retardance, fast axis and rotary power.

Figs. 10f and 10g1 show that changing waveplate selection for a Fig. 9g1 compensator means configuration, and the angle between fast axes of the compensator means members thereof, provides alternative retardation plots over various wavelength ranges. Fig. 10f provides results for wavelengths between 245 and 850 NM, when waveplate selection involves 266 NM and 780 NM, and that angle between the fast axes is 50 degrees. Fig. 10g1 provides results between 380 and 1700 NM, for selection of waveplates at 532 NM and 1550 NM, and an angle between fast axes of 50 degrees. Figs. 10f and 10g1 are included to show that compensator means design can be easily carried out, with the end result that retardations of between 75 and 130 degrees can be achieved over various wavelength ranges.

Fig. 10g2 shows retardation vs. wavelength for a three (3) Zero-Order plate element compensator as can be realized such as suggested by Figs. 9g1, 9g2 and 9j. Note the retardation varies between about 47 degrees and 130 degrees over a wavelength range of 190 to 1700 nm. Said three (3) element compensator comprises a 422 nm quartz Zero Order waveplate sandwiched by two 633 nm quartz Zero Order waveplates. The azimuth of the 422 nm Zero Order waveplate is oriented +41 degrees with respect to the azimuth of the first 633 nm Zero Order plate, and the azimuth of the second 633 nm Zero Order Waveplate is oriented -33 degrees with respect to the azimuth of the first 633 nm Zero Order Waveplate. This compensator design then provides a retardance characteristic which varies over a range less than 90 degrees over a wavelength range, which retardance does not exceed 130 degrees. Note specifically that the retardation vs. wavelength

characteristic retardation range is less than Ninety (90) degrees over a range bounded by Thirty (30.0) to less than one-hundred-thirty-five (135) degrees, over a range of wavelengths specified from a MINW of one-hundred-ninety (190), and a MAXW of seventeen-hundred (1700) nanometers, hence, even though the range of its retardation is between about 47 and 130 degrees, it is covered by Claim language which recited boundaries of 30 and less than 135 degrees.

Figs. 10h - 10o show various experimentally obtained plots utilizing a J.A. Woollam CO. Inc. Rotating Compensator Ellipsometer System, (ie. the "M-2000", Registered Trademark). Curves in Figs. 10h - 10j were extracted using A.C. Normalization while curves in Figs. 10k - 10L were extracted using D.C. Normalization. In particular, Fig. 10h shows azimuthal Compensator Means Retardance as a function of Wavelength. Note that, except for the presence of harmonic "wiggles", (which are due to the imperfect alignment of the "effective" zero-order waveplate), the curve closely corresponds to the calculated curve in Fig. 10c. Fig. 10i shows Effective Input Polarizer Means Azimuthal Angle, (including the rotary effect of the Compensator). Fig. 10j shows the effective Fast Axis of the Compensator Means Azimuthal Orientation. Fig. 10k shows Depolarization factor 'c' and Fig. 10L shows Depolarization factor 'b', as defined in the D.C. term in Eqs. 67. (Note in particular the excellent agreement between plots in Figs. 10c - 10e, and Figs. 10h - 10j).

Figs. 10m - 10o show familiar PSI and DELTA Curves obtained with a Rotating Compensator Ellipsometer System, for Silicon Substrates on, respectively, 1 Micron, 250 Angstroms and 25 Angstroms of SiO_2 on the surface thereof.

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5 It is noted that the described invention easily avoids the limitation inherrent in the Patent to Aspnes, No. 5,877,589, which Patent was identified in the Background Section of this Disclosure, while providing excellent materials system investigation results. Further, the described invention also avoids utilization of "substantially-non-achromatic" compensator means with at least a ninety (90) degree range of retardance variance of an applicable wavelength range, hence avoids the limitations in the Aspnes et al. Patents Nos. 6,320,657 B1 and 10 6,134,012, respectively, again while providing excellent materials system investigation results.

15 It is noted that the terminology Spectroscopic Rotating Compensator Material System Investigation System is to be interpreted sufficiently broadly to include Ellipsometers and Polarimeters with integrated electromagnetic radiation sources, and the like systems. In the Claims the terminology Spectroscopic Ellipsometer is utilized as being generic, with this in mind.

20 As well, it should be understood that a Mathematical Model developed to represent a Spectroscopic Rotating Compensator Material System Investigation System, (ie. Spectroscopic Ellipsometer), can be expressed as explicit equations for 25 Intensity Transfer Function, or as equations for Coefficients of Terms which comprise such as a Transfer Function. However, in the context of performing Regression based evaluation of Calibration Parameters, it is to be understood that a Mathematical Model can "Effectively" provide such equations. 30 That is, a computer program need not calculate a Transfer Function per se. to utilize mathematical relationships inherent therewithin. The terminology "Mathematical Model" and "Transfer Function, and "Coefficients of Terms" are to be interpreted sufficiently broadly so as to include the case where acutal explicit equations therefore are not per se. generated, but where

mathematical relationships inherant "Mathematical Model" and "Transfer Function, and "Coefficients of Terms" are utilized by a Regression based Calibration Parameter evaluation procedure. For instance, Numerical Equivalents to Specific Analytical Functions can be present and utilized in a Computer and be within the scope of the identified terminology, even though specific Analytical Equations are not per se., but only effectually, produced.

It is also to be appreciated that no other Spectroscopic Rotating Compensator Ellipsometer SYSTEM is known which comprises at once:

1. at least one Psuedo-Achromatic Characteristic Rotating Compensator Means (RC);
2. a Dispersive Optics (DO); and
3. a Detector Elements (DE's) containing Detector System (DET) which comprises a Photo Array (PA); such that in use a Multiplicity of Material System, (Sample), (MS) Investigation Wavelengths in a Polychromatic Beam of Electromagnetic Wavelengths are simultaneously Monitored.

In particular, other than as reported in Parent Patent 5,872,630, no known Spectroscopic Rotating Compensator Material System Investigation System utilizes a, (possibly Calibration Parameter Parameterization aided), Mathematical Regression based METHOD approach to Evaluation of Calibration Parameters in a Mathematical Model of such a Spectroscopic Rotating Compensator Material System Investigation System, such that application thereof allows compensating the Psuedo-Achromatic, and other non-Ideal, aspects of a substantially Achromatic or Psuedo-Achromatic Rotating Compensator Means.

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It is emphasized that the described invention is considered to be particularly impressive as it is relatively easily constructed utilizing commercially available "Off-The-Shelf" Diode Array Spectrometer Systems, and non-ideal Compensators. The described invention conveniently provides, in a commercially realizable format, that which was thought to be, prior thereto and the version thereof presented in the Parent Patent 5,872,630, essentially impossible to provide in other than a prohibitively expensive, (and perhaps difficult to calibrate and utilize), single unit format.

It is to be understood that a Photo Array can be comprised of Diode-Elements, Charge-Coupled-Devices, Bucket-Brigade-Devices and equivalents.

It is also noted that Polychromatic Electromagnetic Beam Source can be comprised of a combined plurality/multiplicity of Laser Sources, and that Polychromatic Electromagnetic Beam Source can include an effective Polarizer therewithin, thereby eliminating the need for a separate Polarizer Means. Such cases are to be considered within the scope of the Claims with the effective Polarizer Means considered as the recited Polarizer Means.

It is further to be understood that the terminology "zero-order" is typically utilized herein to mean a single plate retarder/compensator, while the terminology "effective zero-order" is typically utilized herein to mean a zero-order retarder/compensator which is constructed from more than a single plate.

It is also to be understood that while there may be technical definitions in the literature which provide different meanings therefore, the terms "waveplate", "retarder" and

"compensator" are utilized substantially interchangeably in this specification.

It is also to be understood that the terminology "Straight-through" configuration provides as an effective material system, ambient atmosphere.

Finally, it is again noted that Zeiss Diode Array Spectrometer Systems identified by manufacturer numbers in the group: (MMS1 (300-1150 nm); UV/VIS MMS (190-730 nm); UV MMS (190-400 nm); AND IR MMS (900-2400 nm)); as well as Hamamatsu CCD Array Detectors, (Series S7030/S7031), with a quantum efficiency of 40% or more have been successfully utilized in the described invention system. The Hamamatsu CCD array, combined with a diffraction means, is presently preferred.

It is specifically to be understood that the terminology "Compensator means" is to be interpreted sufficiently broadly to include one or more than one compensator(s), and that for the purposes of this Specification and Claim interpretation, that as applied to a Compensator or Compensator Means:

"Substantially Achromatic" means that over a specified range of wavelengths the Retardation varies from just above 0.0 up to about thirty (30) degrees; and

"Pseudo-Achromatic" means that over a specified range of wavelengths the Retardation varies less than Ninety (90) degrees, (ie. the maximum minus minimum retardation is less than 90 degrees), over a range of retardations with a minimum retardation of preferably at least Thirty (30) degrees and a maximum retardation of less than One-Hundred-Thirty-Five (135) Degrees.

"Non-achromatic" is to be interpreted to mean that

retardance entered to a beam of electromagnetic radiation by a retarder/compensator at one wavelength is different from that entered at a different wavelength. For instance, the Aspnes et al. 012, 787 and 657 Patents suggest that if "an effective phase retardation value is induced covering at least from 90 degrees to 180 degrees", (012 Patent), over a range of wavelengths of 200 - 800 nm, such is definitive of a "Substantially-Non- Achromatic" compensator means.

The compensator means of the presently disclosed invention can be termed "Substantially Achromatic", but are more properly termed "Pseudo-achromatic" in that they do not produce uniform retardation at all wavelengths, but produce retardation which is far more uniform than, for instance, waveplates that provides retardance which varies proportional to $(1/\text{wavelength})$.

It is also to be understood that the terminology "Spectroscopic Ellipsometer" utilized in the Claims is referring to the system described in the Detailed Description generally as a "Spectroscopic Rotating Compensator Material System Investigation System". The alternative language is utilized to provide easy Claim language comparison to the Claim language in the Aspnes et al. Patents 6,320,657 B1, 6,134,012, 5,973,787 and 5,877,859. This is done for the purpose of avoiding confusion as to what the J.A. Woollam Co. Inc. and the Thermawave Inc. Patents respectively protect.

Having hereby disclosed the subject matter of this invention, it should be obvious that many modifications, substitutions and variations of the present invention are possible in light of the teachings. It is therefore to be understood that the present invention can be practiced other than as specifically described, and should be limited in breadth and scope only by the Claims.